

## ADS131E0x 4-, 6-, and 8-Channel, 24-Bit, Simultaneously-Sampling, Delta-Sigma ADC

### 1 Features

- Eight Differential ADC Inputs
- Outstanding Performance:
  - Dynamic Range: 118 dB at 1 kSPS
  - Crosstalk: –110 dB
  - THD: –90 dB at 50 Hz and 60 Hz
- Analog Supply Range Options:
  - 3 V to 5 V (Unipolar)
  - $\pm 2.5$  V (Bipolar, Allows DC-Coupling)
- Digital: 1.8 V to 3.6 V
- Low Power: 2 mW per Channel
- Data Rates: 1, 2, 4, 8, 16, 32, and 64 kSPS
- Programmable Gains: 1, 2, 4, 8, and 12
- Fault Detection and Device Testing Capability
- SPI™ Data Interface and Four GPIOs
- Package: TQFP-64 (PAG)
- Operating Temperature Range: –40°C to +105°C

### 2 Applications

- Power Protection: Circuit Breakers, and Relay Protection
- Energy Metering: Single Phase, Polyphase, and Power Quality
- Battery Test Systems
- Test and Measurement
- Simultaneous Sampling Data Acquisition Systems

### 3 Description

The ADS131E0x are a family of multichannel, simultaneous sampling, 24-bit, delta-sigma ( $\Delta\Sigma$ ), analog-to-digital converters (ADCs) with a built-in programmable gain amplifier (PGA), internal reference, and an onboard oscillator. The ADC wide dynamic range, scalable data rates, and internal fault detect monitors make the ADS131E0x attractive in industrial power monitoring and protection as well as test and measurement applications. True high-impedance inputs enable the ADS131E0x to directly interface with a resistor-divider network or a voltage transformer to measure line voltage, or a current transformer or Rogowski coil to measure line current. With high integration levels and exceptional performance, the ADS131E0x family enables the creation of scalable industrial power systems at significantly reduced size, power, and low overall cost.

The ADS131E0x have a flexible input multiplexer per channel that can be independently connected to the internally-generated signals for test, temperature, and fault detection. Fault detection can be implemented internal to the device, using the integrated comparators with digital-to-analog converter (DAC)-controlled trigger levels. The ADS131E0x can operate at data rates as high as 64 kSPS.

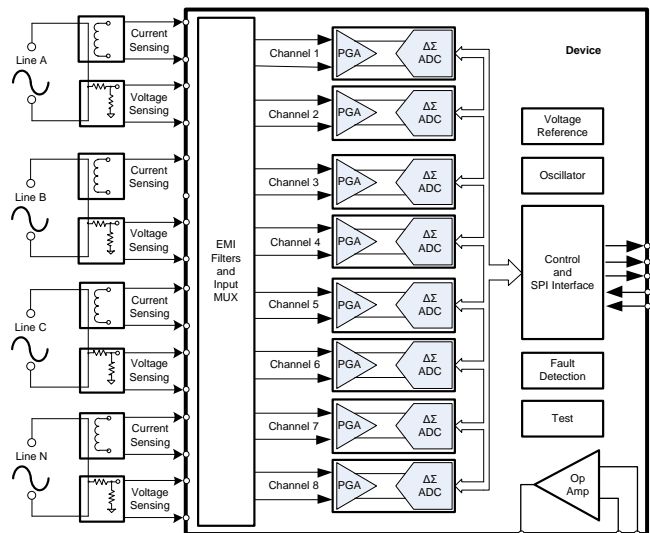
These complete analog front-end (AFE) solutions are packaged in a TQFP-64 package and are specified over the industrial temperature range of –40°C to +105°C.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
ADS131E0x	TQFP (64)	10.00 mm x 10.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### ADS131E08 Simplified Schematic



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Revision B (December 2013) to Revision C</b>	<b>Page</b>
• Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	<b>1</b>
• Changed formatting of <i>Thermal Information</i> table note .....	<b>8</b>

<b>Changes from Revision A (April 2013) to Revision B</b>	<b>Page</b>
• Deleted device graphic.....	<b>1</b>
• Changed ADS131E0x family description to 24-bits only throughout document.....	<b>1</b>
• Added <i>AVSS to DGND</i> row to Absolute Maximum Ratings table .....	<b>7</b>
• Changed minimum specification to External Reference, <i>VREFP</i> parameter in Electrical Characteristics table .....	<b>7</b>
• Changed conditions in <a href="#">Figure 10</a> .....	<b>13</b>
• Changed conditions in <a href="#">Figure 11</a> .....	<b>13</b>
• Changed <i>START Opcode</i> to <i>START</i> in Figure 39.....	<b>28</b>
• Changed <i>Reset (RESET)</i> section for clarity .....	<b>29</b>
• Changed <i>Power-Up Sequencing</i> section.....	<b>61</b>

<b>Changes from Original (June 2012) to Revision A</b>	<b>Page</b>
• Deleted <i>AGND to DGND</i> row from Absolute Maximum Ratings table .....	<b>7</b>
• Changed value of <i>Digital input to DVDD</i> row in Absolute Maximum Ratings table.....	<b>7</b>
• Added minimum and maximum specifications to External Reference, <i>Reference input voltage</i> parameter in Electrical	

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Characteristics table .....	7
• Added minimum and maximum specifications to External Reference, <i>VREFP</i> parameter in Electrical Characteristics table .....	7
• Changed Channel Performance (AC Performance), <i>Accuracy</i> parameter in Electrical Characteristics table .....	9
• Changed Internal Reference, $V_O$ parameter in Electrical Characteristics table .....	9
• Changed Internal Reference, <i>Temperature drift</i> parameter in Electrical Characteristics table .....	9
• Added <a href="#">Figure 15</a> .....	14

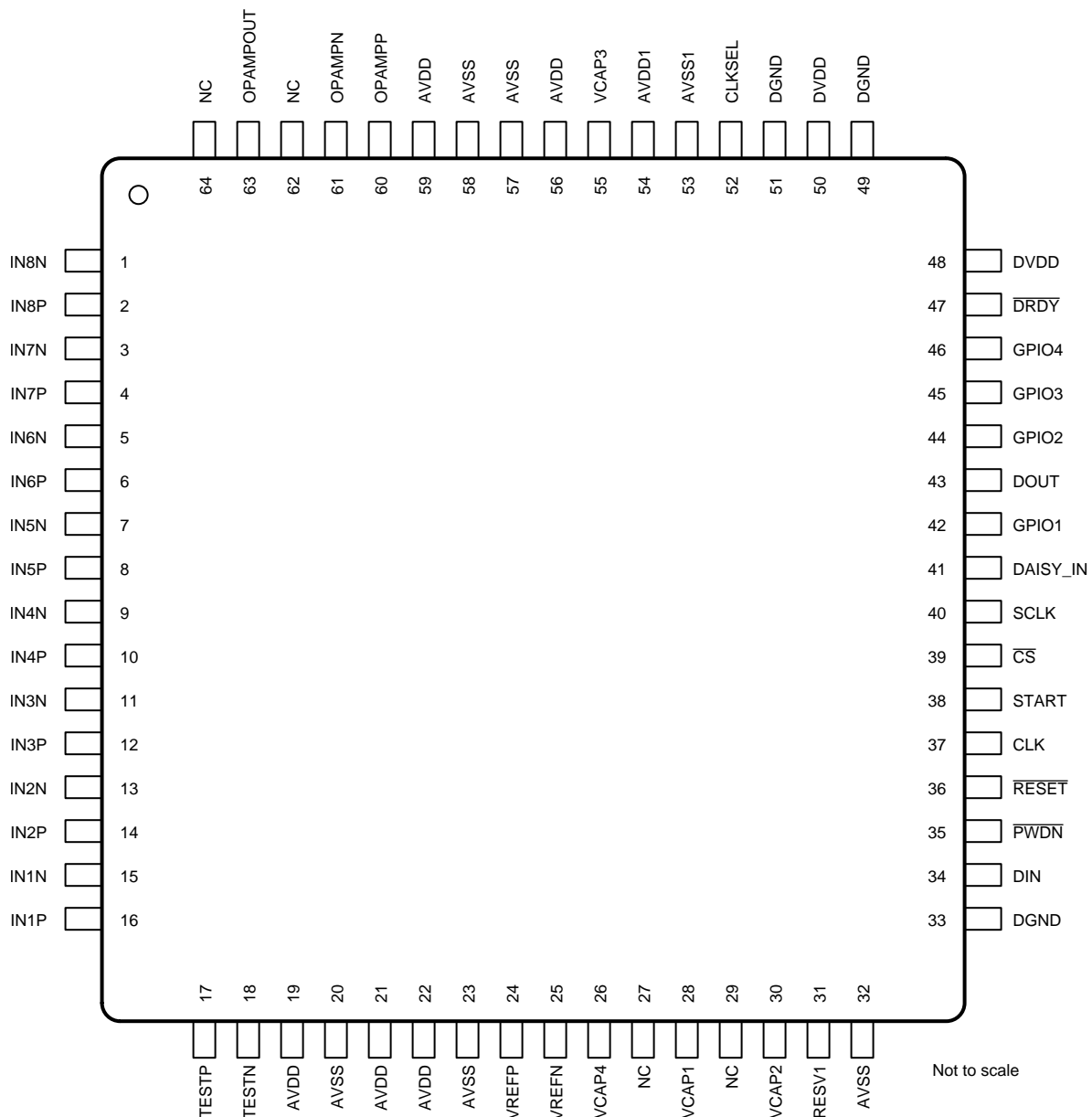
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## 5 Device Comparison

PRODUCT	NO. OF INPUTS	REFERENCE OPTIONS	RESOLUTION (Bits)	POWER-UP TIME (ms)
ADS130E08	8	Internal, external	16	128
ADS131E04	4	Internal, external	24	128
ADS131E06	6	Internal, external	24	128
ADS131E08	8	Internal, external	24	128
ADS131E08S	8	Internal only	24	3

## 6 Pin Configuration and Functions

PAG Package  
64-Pin TQFP  
Top View



### Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
AVDD	19, 21, 22, 56, 59	Supply	Analog supply. Connect a 1- $\mu$ F (or larger) capacitor to AVSS for each AVDD pin.
AVDD1	54	Supply	Charge pump analog supply. Connect a 1- $\mu$ F (or larger) capacitor to AVSS1.
AVSS	20, 23, 32, 57, 58	Supply	Analog ground
AVSS1	53	Supply	Charge pump analog ground
$\overline{\text{CS}}$	39	Digital input	Chip select; active low
CLK	37	Digital input	Master clock input. Connect to DGND if unused.
CLKSEL	52	Digital input	Master clock select
DAISY_IN	41	Digital input	Daisy-chain input. Connect to DGND if unused.
DGND	33, 49, 51	Supply	Digital ground
DIN	34	Digital input	Serial data input
DOUT	43	Digital output	Serial data output
$\overline{\text{DRDY}}$	47	Digital output	Data ready; active low. Connect to DGND with a 10-k $\Omega$ resistor if unused.
DVDD	48, 50	Supply	Digital core power supply. Connect a 1- $\mu$ F (or larger) capacitor to DGND for each DVDD pin.
GPIO1	42	Digital input/output	General-purpose input/output pin 1. Connect to DGND with a 10-k $\Omega$ resistor if unused.
GPIO2	44	Digital input/output	General-purpose input/output pin 2. Connect to DGND with a 10-k $\Omega$ resistor if unused.
GPIO3	45	Digital input/output	General-purpose input/output pin 3. Connect to DGND with a 10-k $\Omega$ resistor if unused.
GPIO4	46	Digital input/output	General-purpose input/output pin 4. Connect to DGND with a 10-k $\Omega$ resistor if unused.
IN1N <sup>(1)</sup>	15	Analog input	Negative analog input 1
IN1P <sup>(1)</sup>	16	Analog input	Positive analog input 1
IN2N <sup>(1)</sup>	13	Analog input	Negative analog input 2
IN2P <sup>(1)</sup>	14	Analog input	Positive analog input 2
IN3N <sup>(1)</sup>	11	Analog input	Negative analog input 3
IN3P <sup>(1)</sup>	12	Analog input	Positive analog input 3
IN4N <sup>(1)</sup>	9	Analog input	Negative analog input 4
IN4P <sup>(1)</sup>	10	Analog input	Positive analog input 4
IN5N <sup>(1)</sup>	7	Analog input	Negative analog input 5 (ADS131E06 and ADS131E08 only)
IN5P <sup>(1)</sup>	8	Analog input	Positive analog input 5 (ADS131E06 and ADS131E08 only)
IN6N <sup>(1)</sup>	5	Analog input	Negative analog input 6 (ADS131E06 and ADS131E08 only)
IN6P <sup>(1)</sup>	6	Analog input	Positive analog input 6 (ADS131E06 and ADS131E08 only)
IN7N <sup>(1)</sup>	3	Analog input	Negative analog input 7 (ADS131E08 only)
IN7P <sup>(1)</sup>	4	Analog input	Positive analog input 7 (ADS131E08 only)
IN8N <sup>(1)</sup>	1	Analog input	Negative analog input 8 (ADS131E08 only)
IN8P <sup>(1)</sup>	2	Analog input	Positive analog input 8 (ADS131E08 only)
NC	27, 29, 62, 64	—	No connection, leave floating. Can be connected to AVDD or AVSS with a 10-k $\Omega$ or higher resistor.
OPAMPN	61	Analog input	Op amp inverting input; leave floating if unused and power-down the op amp.
OPAMPP	60	Analog input	Op amp noninverting input; leave floating if unused and power-down the op amp.
OPAMPOUT	63	Analog output	Op amp output; leave floating if unused and power-down the op amp.
$\overline{\text{PWDN}}$	35	Digital input	Power-down; active low

(1) Connect any unused or powered-down analog input pins to AVDD.

**Pin Functions (continued)**

PIN		I/O	DESCRIPTION
NAME	NO.		
RESET	36	Digital input	System reset; active low
RESV1	31	Digital input	Reserved for future use. Connect directly to DGND.
SCLK	40	Digital input	Serial clock input
START	38	Digital input	Start conversion
TESTN	18	Analog input/output	Test signal, negative pin. See the <a href="#">Unused Inputs and Outputs</a> section for unused pins.
TESTP	17	Analog input/output	Test signal, positive pin. See the <a href="#">Unused Inputs and Outputs</a> section for unused pins.
VCAP1	28	Analog output	Analog bypass capacitor. Connect a 22- $\mu$ F capacitor to AVSS.
VCAP2	30	Analog output	Analog bypass capacitor. Connect a 1- $\mu$ F capacitor to AVSS.
VCAP3	55	Analog output	Analog bypass capacitor. Connect a parallel combination of 1- $\mu$ F and 0.1- $\mu$ F capacitors to AVSS.
VCAP4	26	Analog output	Analog bypass capacitor. Connect a 1- $\mu$ F capacitor to AVSS.
VREFN	25	Analog input	Negative reference voltage. Connect to AVSS
VREFP	24	Analog input/output	Positive reference voltage. Connect a minimum 10- $\mu$ F capacitor to VREFN.

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Power-supply voltage	AVDD to AVSS	-0.3	5.5	V
	AVSS to DGND	-3	0.2	
	DVDD to DGND	-0.3	3.9	
Analog input voltage	Analog input to AVSS	AVSS - 0.3	AVDD + 0.3	V
Digital input voltage	Digital input to DVDD	DGND - 0.3	DVDD + 0.3	V
Input current	Momentary	-100	100	mA
	Continuous, all other pins except power-supply pins	-10	10	
Temperature	Junction, T <sub>J</sub>		150	°C
	Storage, T <sub>stg</sub>	-60	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±1000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT	
<b>POWER SUPPLY</b>						
AVDD	Analog power supply	AVDD to AVSS	2.7	5.0	5.25	V
DVDD	Digital power supply	DVDD to DGND	1.7	1.8	3.6	V
	Analog to digital supply	AVDD to DVDD	-2.1		3.6	V
<b>ANALOG INPUTS</b>						
V <sub>IN</sub>	Differential input voltage	V <sub>IN</sub> = V <sub>(INxP)</sub> - V <sub>(INxN)</sub>	-V <sub>REF</sub> / Gain		V <sub>REF</sub> / Gain	V
V <sub>CM</sub>	Common-mode input voltage	V <sub>CM</sub> = (V <sub>(INxP)</sub> - V <sub>(INxN)</sub> ) / 2	See the <a href="#">Input Common-Mode Range</a> section			V
<b>VOLTAGE REFERENCE INPUTS</b>						
V <sub>REF</sub>	Reference input voltage	AVDD = 3 V, V <sub>REF</sub> = (V <sub>VREFP</sub> - V <sub>VREFN</sub> )	2	2.5	AVDD	V
		AVDD = 5 V, V <sub>REF</sub> = (V <sub>VREFP</sub> - V <sub>VREFN</sub> )	2	4	AVDD	V
V <sub>REFN</sub>	Negative reference input		AVSS			V
V <sub>REFP</sub>	Positive input		AVDD - 3	AVSS + 2.5	AVDD	V
<b>EXTERNAL CLOCK SOURCE</b>						
f <sub>CLK</sub>	Master clock rate	CLKSEL pin = 0, (AVDD - AVSS) = 3 V	1.7	2.048	2.25	MHz
		CLKSEL pin = 0, (AVDD - AVSS) = 5 V	1.0	2.048	2.25	
<b>DIGITAL INPUTS</b>						
	Input voltage		DGND - 0.1		DVDD + 0.1	V
<b>TEMPERATURE RANGE</b>						
T <sub>A</sub>	Operating ambient temperature		-40		105	°C

## 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		ADS131E0x	UNIT
		PAG (TQFP)	
		64 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	35	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	31	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	26	°C/W
$\psi_{JT}$	Junction-to-top characterization parameter	0.1	°C/W
$\psi_{JB}$	Junction-to-board characterization parameter	NA	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	NA	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.



## 7.5 Electrical Characteristics

Minimum and maximum specifications apply from  $-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ . Typical specifications are at  $25^{\circ}\text{C}$ . All specifications are at  $\text{DVDD} = 1.8\text{ V}$ ,  $\text{AVDD} = 3\text{ V}$ ,  $\text{AVSS} = 0\text{ V}$ ,  $V_{\text{REF}} = 2.4\text{ V}$ , external  $f_{\text{CLK}} = 2.048\text{ MHz}$ , data rate = 8 kSPS, and gain = 1, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>ANALOG INPUTS</b>						
$C_i$	Input capacitance			20		pF
$I_{\text{IB}}$	Input bias current	PGA output in normal range		5		nA
	DC input impedance			200		MΩ
<b>PGA PERFORMANCE</b>						
	Gain settings			1, 2, 4, 8, 12		
BW	Bandwidth			See <a href="#">Table 3</a>		
<b>ADC PERFORMANCE</b>						
DR	Data rate	$f_{\text{CLK}} = 2.048\text{ MHz}$	1		64	kSPS
	Resolution	DR = 1 kSPS, 2 kSPS, 4 kSPS, 8 kSPS, and 16 kSPS	24			Bits
		DR = 32 kSPS and 64 kSPS	16			Bits
<b>CHANNEL PERFORMANCE (DC PERFORMANCE)</b>						
INL	Integral nonlinearity	Full-scale, best fit		10		ppm
	Dynamic range	G = 1	105			dB
		Gain settings other than 1	See the <a href="#">Noise Measurements</a> section			
$E_{\text{O}}$	Offset error			350		μV
	Offset error drift			0.65		μV/°C
$E_{\text{G}}$	Gain error	Excluding voltage reference error		0.1%		
	Gain drift	Excluding voltage reference drift		3		ppm/°C
	Gain match between channels			0.2		% of FS
<b>CHANNEL PERFORMANCE (AC PERFORMANCE)</b>						
CMRR	Common-mode rejection ratio	$f_{\text{CM}} = 50\text{ Hz}$ and $60\text{ Hz}^{(1)}$		-110		dB
PSRR	Power-supply rejection ratio	$f_{\text{PS}} = 50\text{ Hz}$ and $60\text{ Hz}$		-80		dB
	Crosstalk	$f_{\text{IN}} = 50\text{ Hz}$ and $60\text{ Hz}$		-110		dB
	Accuracy	3000:1 dynamic range with a 1-second measurement ( $V_{\text{RMS}} / I_{\text{RMS}}$ )	AVDD = 3 V, $V_{\text{REF}} = 2.4\text{ V}$	0.04%		
			AVDD = 5 V, $V_{\text{REF}} = 4\text{ V}$	0.025%		
SNR	Signal-to-noise ratio	$f_{\text{IN}} = 50\text{ Hz}$ and $60\text{ Hz}$ , gain = 1		107		dB
THD	Total harmonic distortion	10 Hz, -0.5 dBFS		-93		dB
<b>INTERNAL REFERENCE</b>						
$V_{\text{REF}}$	Output voltage	$T_{\text{A}} = 25^{\circ}\text{C}$ , $V_{\text{REF}} = 2.4\text{ V}$	2.394	2.4	2.406	V
		$T_{\text{A}} = 25^{\circ}\text{C}$ , $V_{\text{REF}} = 4\text{ V}$		4		V
	$V_{\text{REF}}$ accuracy			±0.2%		
	Temperature drift	$T_{\text{A}} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$		20		ppm/°C
	Start-up time	Settled to 0.2%		150		ms
<b>EXTERNAL REFERENCE</b>						
	Input impedance			6		kΩ
<b>INTERNAL OSCILLATOR</b>						
	Accuracy			±2%		
		$T_{\text{A}} = 25^{\circ}\text{C}$			±0.5%	
		$T_{\text{A}} = -40^{\circ}\text{C}$ to $105^{\circ}\text{C}$			2.5%	
	Internal oscillator clock frequency	Nominal frequency		2.048		MHz
	Internal oscillator start-up time			20		μs
	Internal oscillator power consumption			120		μW
<b>FAULT DETECT AND ALARM</b>						
	Comparator threshold accuracy			±30		mV

(1) CMRR is measured with a common-mode signal of  $(\text{AVSS} + 0.3\text{ V})$  to  $(\text{AVDD} - 0.3\text{ V})$ . The values indicated are the minimum of the eight channels.

## Electrical Characteristics (continued)

Minimum and maximum specifications apply from  $-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ . Typical specifications are at  $25^{\circ}\text{C}$ . All specifications are at  $\text{DVDD} = 1.8\text{ V}$ ,  $\text{AVDD} = 3\text{ V}$ ,  $\text{AVSS} = 0\text{ V}$ ,  $V_{\text{REF}} = 2.4\text{ V}$ , external  $f_{\text{CLK}} = 2.048\text{ MHz}$ , data rate = 8 kSPS, and gain = 1, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OPERATIONAL AMPLIFIER</b>						
	Integrated noise	0.1 Hz to 250 Hz		9		$\mu\text{V}_{\text{RMS}}$
	Noise density	2 kHz		120		$\text{nV}/\sqrt{\text{Hz}}$
GBP	Gain bandwidth product	50 k $\Omega$    10-pF load		100		kHz
SR	Slew rate	50 k $\Omega$    10-pF load		0.25		V/ $\mu\text{s}$
	Load current			50		$\mu\text{A}$
THD	Total harmonic distortion	$f_{\text{IN}} = 100\text{ Hz}$		70		dB
	Common-mode input range		$\text{AVSS} + 0.7$		$\text{AVDD} - 0.3$	V
	Quiescent power consumption			20		$\mu\text{A}$
<b>SYSTEM MONITORS</b>						
Supply reading error	Analog			2%		
	Digital			2%		
Device wake up		From power-up to $\overline{\text{DRDY}}$ low		150		ms
		STANDBY mode		31.25		$\mu\text{s}$
Temperature sensor reading	Voltage	$T_{\text{A}} = 25^{\circ}\text{C}$		145		mV
	Coefficient			490		$\mu\text{V}/^{\circ}\text{C}$
<b>SELF-TEST SIGNAL</b>						
Signal frequency	See the <a href="#">Register Map</a> section for settings			$f_{\text{CLK}} / 2^{21}$		Hz
				$f_{\text{CLK}} / 2^{20}$		
Signal voltage	See the <a href="#">Register Map</a> section for settings			$\pm 1$		mV
				$\pm 2$		
<b>DIGITAL INPUT AND OUTPUT (DVDD = 1.8 V to 3.6 V)</b>						
$V_{\text{IH}}$	Logic level, input voltage	High		0.8 DVDD	DVDD+0.1	V
$V_{\text{IL}}$		Low		-0.1	0.2 DVDD	V
$V_{\text{OH}}$	Logic level, output voltage	High	$I_{\text{OH}} = -500\ \mu\text{A}$	0.9 DVDD		V
$V_{\text{OL}}$		Low	$I_{\text{OL}} = +500\ \mu\text{A}$		0.1 DVDD	V
$I_{\text{IN}}$	Input current	$0\text{ V} < V_{\text{DigitalInput}} < \text{DVDD}$		-10	10	$\mu\text{A}$

## Electrical Characteristics (continued)

Minimum and maximum specifications apply from  $-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ . Typical specifications are at  $25^{\circ}\text{C}$ . All specifications are at  $\text{DVDD} = 1.8\text{ V}$ ,  $\text{AVDD} = 3\text{ V}$ ,  $\text{AVSS} = 0\text{ V}$ ,  $V_{\text{REF}} = 2.4\text{ V}$ , external  $f_{\text{CLK}} = 2.048\text{ MHz}$ , data rate = 8 kSPS, and gain = 1, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT (OPERATIONAL AMPLIFIER TURNED OFF)</b>						
$I_{\text{AVDD}}$	Normal mode	$\text{AVDD} - \text{AVSS} = 3\text{ V}$		5.1		mA
		$\text{AVDD} - \text{AVSS} = 5\text{ V}$		5.8		mA
$\text{DVDD} = 3.3\text{ V}$			1		mA	
$\text{DVDD} = 1.8\text{ V}$			0.4		mA	
$I_{\text{DVDD}}$						
<b>POWER DISSIPATION (ANALOG SUPPLY = 3 V)</b>						
Quiescent power dissipation	ADS131E04	Normal mode		9.3	10.2	mW
		Power-down mode		10		$\mu\text{W}$
		Standby mode		2		mW
	ADS131E06	Normal mode		12.7	13.5	mW
		Power-down mode		10		$\mu\text{W}$
		Standby mode		2		mW
	ADS131E08	Normal mode		16	17.6	mW
		Power-down mode		10		$\mu\text{W}$
		Standby mode		2		mW
<b>POWER DISSIPATION (ANALOG SUPPLY = 5 V)</b>						
Quiescent power dissipation	ADS131E04	Normal mode		18		mW
		Power-down mode		20		$\mu\text{W}$
		Standby mode		4.2		mW
	ADS131E06	Normal mode		24.3		mW
		Power-down mode		20		$\mu\text{W}$
		Standby mode		4.2		mW
	ADS131E08	Normal mode		29.7		mW
		Power-down mode		20		$\mu\text{W}$
		Standby mode		4.2		mW

## 7.6 Timing Requirements

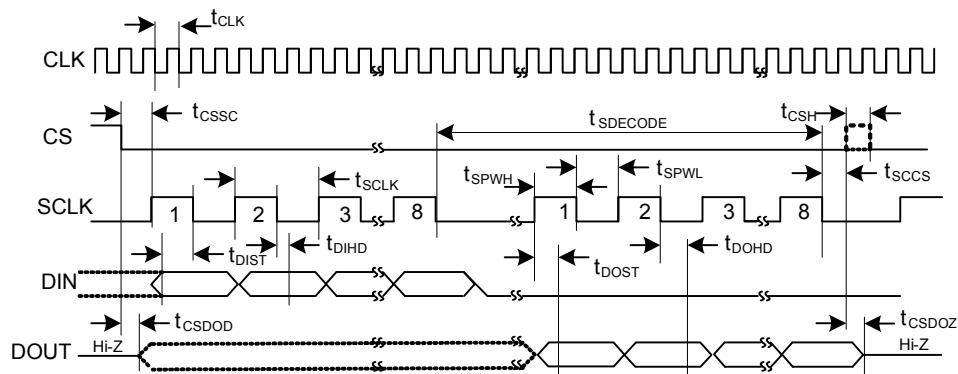
over operating ambient temperature range and DVDD = 1.7 V to 3.6 V (unless otherwise noted)

		2.7 V ≤ DVDD ≤ 3.6 V		1.7 V ≤ DVDD ≤ 2.0 V		UNIT
		MIN	MAX	MIN	MAX	
t <sub>CLK</sub>	Master clock period	444	588	444	588	ns
t <sub>CSSC</sub>	Delay time, first SCLK rising edge after $\overline{\text{CS}}$ falling edge	6		17		ns
t <sub>SCLK</sub>	SCLK period	50		66.6		ns
t <sub>SPWH, L</sub>	Pulse duration, SCLK high or low	15		25		ns
t <sub>DIST</sub>	Setup time, DIN valid before SCLK falling edge	10		10		ns
t <sub>DIHD</sub>	Hold time, DIN valid after SCLK falling edge	10		11		ns
t <sub>CSH</sub>	Pulse duration, $\overline{\text{CS}}$ high	2		2		t <sub>CLK</sub>
t <sub>SCCS</sub>	Delay time, $\overline{\text{CS}}$ rising edge after final SCLK falling edge	4		4		t <sub>CLK</sub>
t <sub>SDECODE</sub>	Command decode time	4		4		t <sub>CLK</sub>
t <sub>DISCK2ST</sub>	Setup time, DAISY_IN valid before SCLK falling edge	10		10		ns
t <sub>DISCK2HT</sub>	Hold time, DAISY_IN valid after SCLK falling edge	10		10		ns

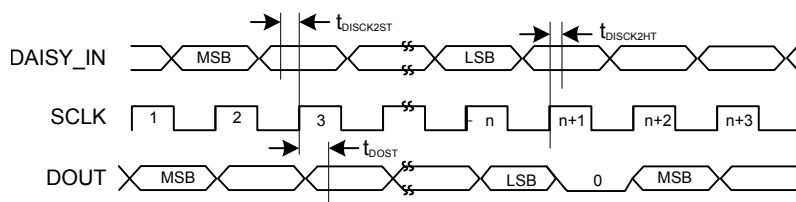
## 7.7 Switching Characteristics

over operating ambient temperature range, DVDD = 1.7 V to 3.6 V, and load on DOUT = 20 pF || 100 kΩ (unless otherwise noted)

PARAMETER		2.7 V ≤ DVDD ≤ 3.6 V		1.7 V ≤ DVDD ≤ 2.0 V		UNIT
		MIN	MAX	MIN	MAX	
t <sub>CSDOD</sub>	Propagation delay time, $\overline{\text{CS}}$ falling edge to DOUT driven	10		20		ns
t <sub>DOST</sub>	Propagation delay time, SCLK rising edge to valid new DOUT		17		32	ns
t <sub>DOHD</sub>	Hold time, SCLK falling edge to invalid DOUT	10		10		ns
t <sub>CSDOZ</sub>	Propagation delay time, $\overline{\text{CS}}$ rising edge to DOUT high impedance		10		20	ns



NOTE: SPI settings are CPOL = 0 and CPHA = 1.

**Figure 1. Serial Interface Timing**


(1) n = Number of channels × resolution + 24 bits. Number of channels is 8; resolution is 24-bit.

**Figure 2. Daisy-Chain Interface Timing**

### 7.8 Typical Characteristics

all plots are at  $T_A = 25^\circ\text{C}$ ,  $AV_{DD} = 3\text{ V}$ ,  $AV_{SS} = 0\text{ V}$ ,  $DV_{DD} = 1.8\text{ V}$ , internal  $V_{REFP} = 2.4\text{ V}$ ,  $V_{REFN} = AV_{SS}$ , external clock = 2.048 MHz, data rate = 8 kSPS, and gain = 1, unless otherwise noted.

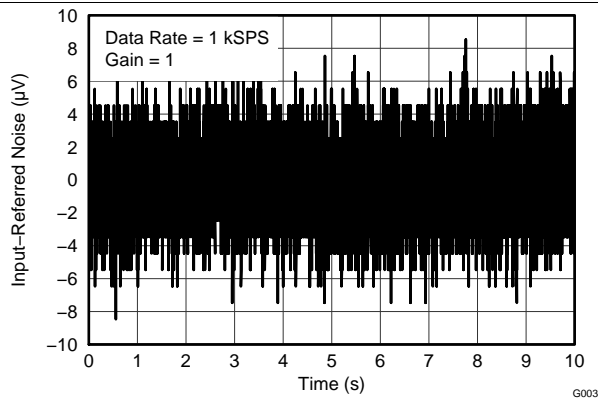


Figure 3. Input-Referred Noise

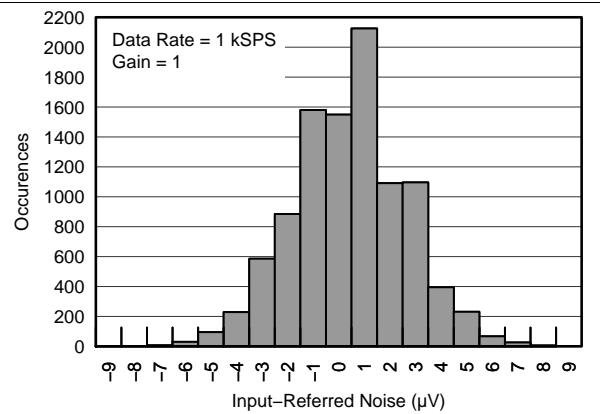


Figure 4. Noise Histogram

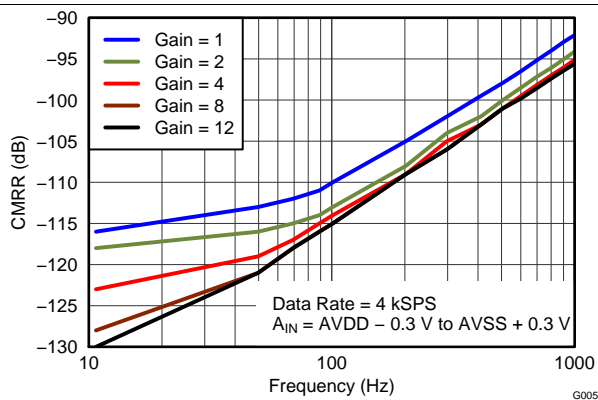


Figure 5. CMRR vs Frequency

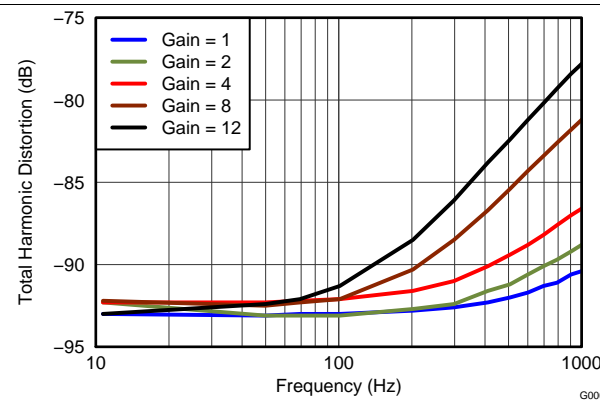


Figure 6. THD vs Frequency

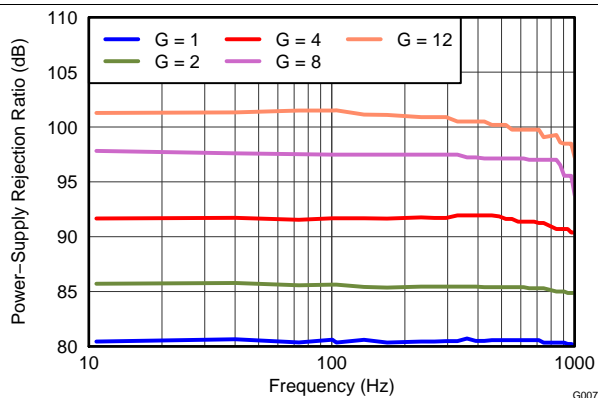


Figure 7. PSRR vs Frequency

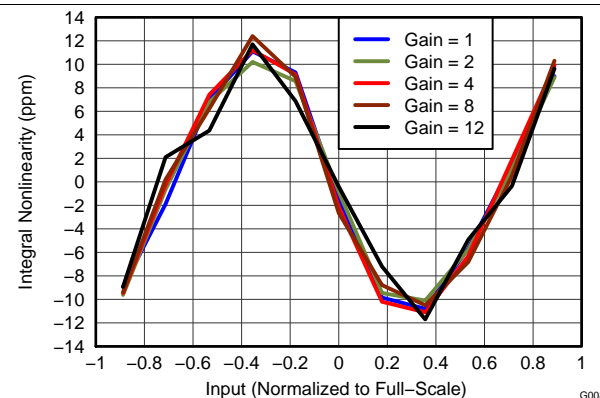
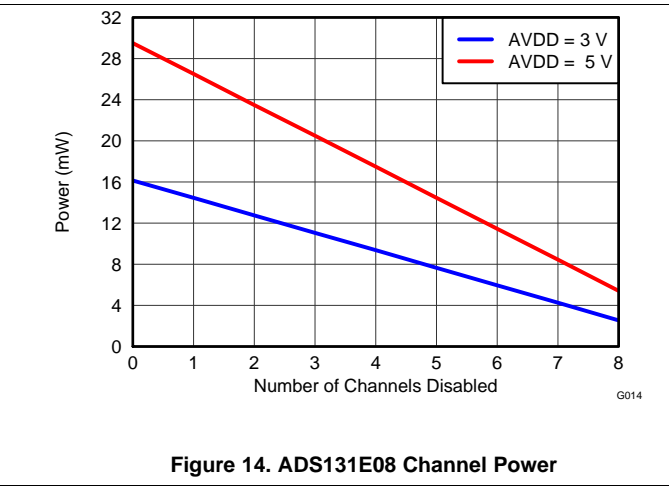
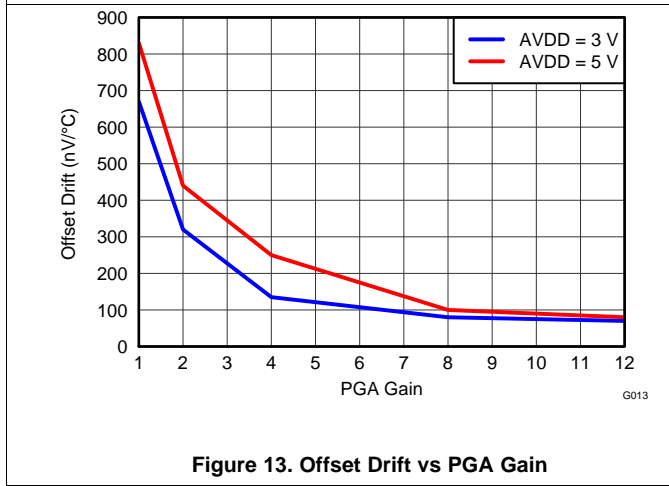
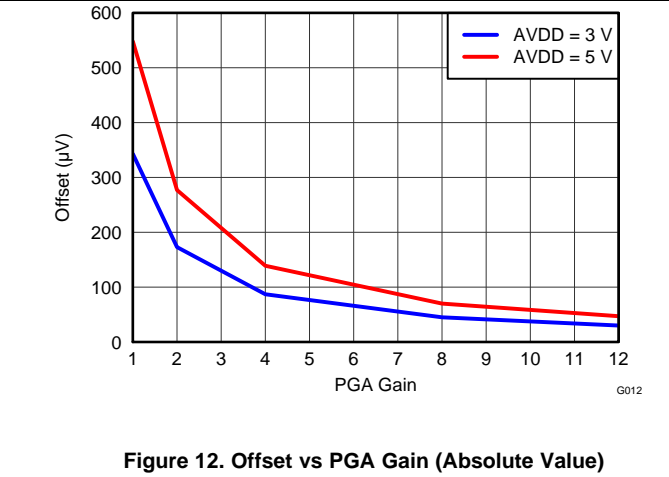
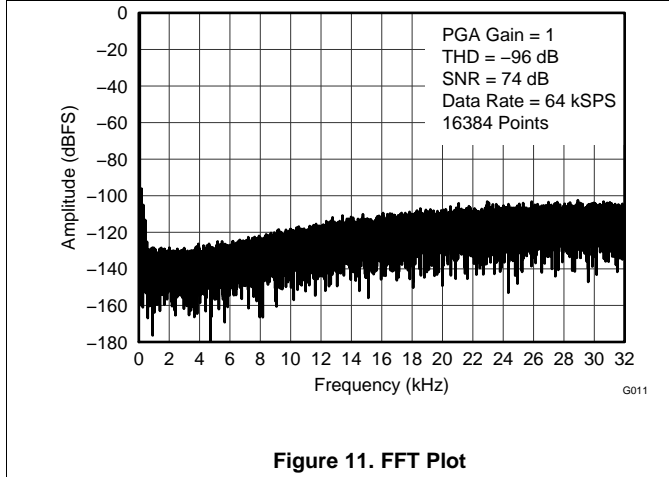
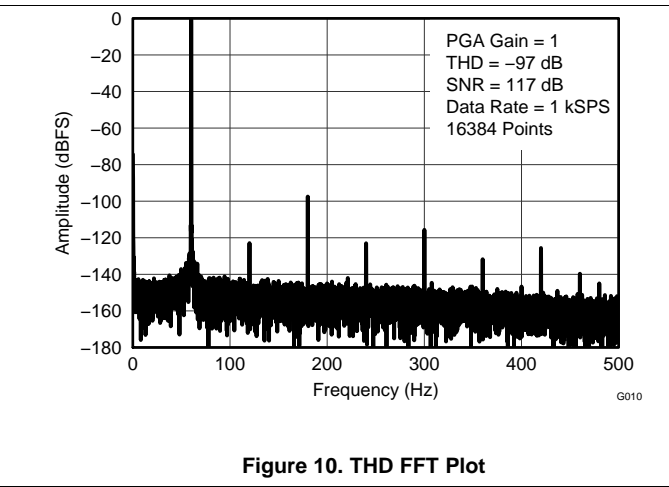
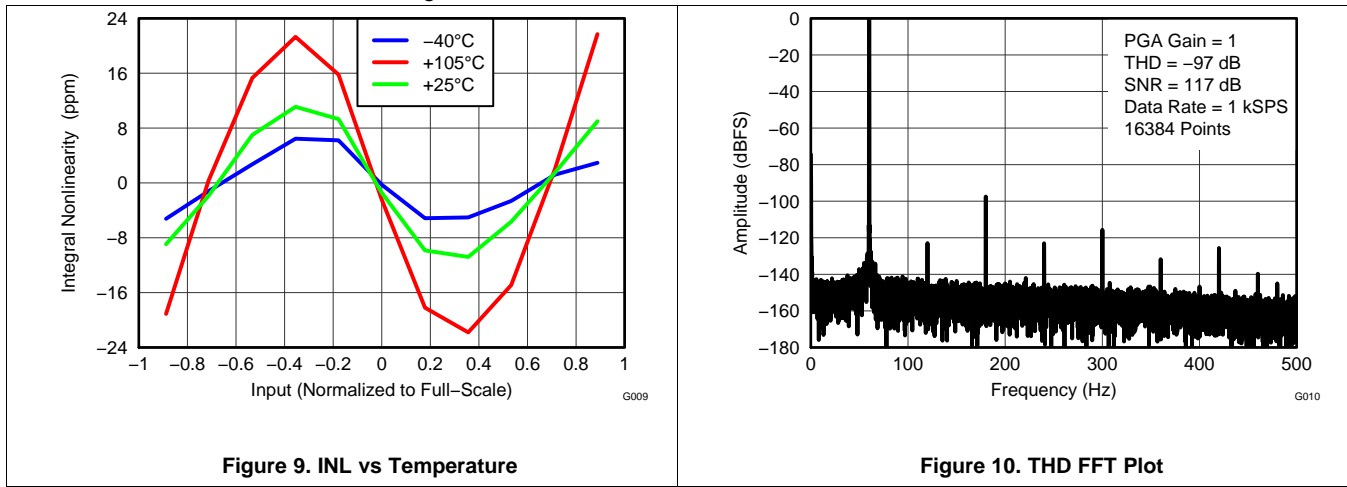


Figure 8. INL vs PGA Gain

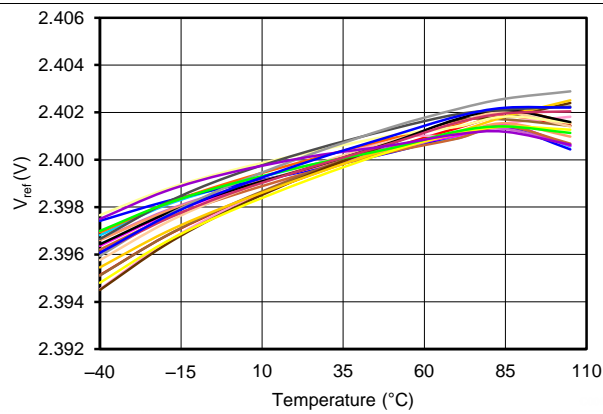
### Typical Characteristics (continued)

all plots are at  $T_A = 25^\circ\text{C}$ ,  $AVDD = 3\text{ V}$ ,  $AVSS = 0\text{ V}$ ,  $DVDD = 1.8\text{ V}$ , internal  $VREFP = 2.4\text{ V}$ ,  $VREFN = AVSS$ , external clock = 2.048 MHz, data rate = 8 kSPS, and gain = 1, unless otherwise noted.



**Typical Characteristics (continued)**

all plots are at  $T_A = 25^\circ\text{C}$ ,  $AVDD = 3\text{ V}$ ,  $AVSS = 0\text{ V}$ ,  $DVDD = 1.8\text{ V}$ , internal  $V_{REFP} = 2.4\text{ V}$ ,  $V_{REFN} = AVSS$ , external clock = 2.048 MHz, data rate = 8 kSPS, and gain = 1, unless otherwise noted.



**Figure 15. Internal  $V_{REF}$  vs Temperature**

## 8 Parameter Measurement Information

### 8.1 Noise Measurements

Adjust the data rate and PGA gain to optimize the ADS131E0x noise performance. When averaging is increased by reducing the data rate, noise drops correspondingly. Increasing the PGA gain reduces the input-referred noise, which is particularly useful when measuring low-level signals. [Table 1](#) summarizes the ADS131E0x noise performance with a 3-V analog power supply. [Table 2](#) summarizes the ADS131E0x noise performance with a 5-V analog power supply. Data are representative of typical noise performance at  $T_A = 25^\circ\text{C}$ . Data shown are the result of averaging the readings from multiple devices and are measured with the inputs shorted together. A minimum of 1000 consecutive readings are used to calculate the RMS noise for each reading. For the two highest data rates, noise is limited by the ADC quantization noise and does not have a Gaussian distribution. [Table 1](#) and [Table 2](#) show measurements taken with an internal reference. Data are representative of the ADS131E0x noise performance shown in both effective number of bits (ENOB) and dynamic range when using a low-noise external reference (such as the [REF5025](#)). ENOB data in [Table 1](#) and [Table 2](#) are calculated using [Equation 1](#) and dynamic range data in [Table 1](#) and [Table 2](#) are calculated using [Equation 2](#).

$$\text{ENOB} = \log_2 \left| \frac{\text{VREF}}{\sqrt{2} \times V_{\text{RMS\_Noise}} \times \text{Gain}} \right| \quad (1)$$

$$\text{Dynamic Range} = 20 \times \log_{10} \left| \frac{\text{VREF}}{\sqrt{2} \times V_{\text{RMS\_Noise}} \times \text{Gain}} \right| \quad (2)$$

**Table 1. Input-Referred Noise, 3-V Analog Supply, and 2.4-V Reference**

DR BITS (CONFIG1 Register)	OUTPUT DATA RATE (kSPS)	-3-dB BANDWIDTH (Hz)	PGA GAIN									
			x1		x2		x4		x8		x12	
			DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB
000	64	16768	74.1	12.31	74.1	12.30	74.0	12.29	74.0	12.29	73.9	12.27
001	32	8384	89.6	14.89	89.6	14.88	89.4	14.85	88.6	14.71	87.6	14.55
010	16	4192	102.8	17.07	102.3	16.99	100.6	16.72	97.1	16.12	94.2	15.65
011	8	2096	108.2	18.0	107.4	17.9	105.2	17.5	101.6	16.9	98.9	16.5
100	4	1048	111.4	18.6	109.4	18.4	107.4	18.1	103.5	17.4	100.5	17.0
101	2	524	114.6	19.1	113.7	19.0	111.4	18.6	107.7	18.0	104.9	17.5
110	1	262	117.7	19.6	116.8	19.5	114.5	19.1	110.7	18.5	108.0	18.0

**Table 2. Input-Referred Noise, 5-V Analog Supply, And 4-V Reference**

DR BITS (CONFIG1 Register)	OUTPUT DATA RATE (kSPS)	-3-dB BANDWIDTH (Hz)	PGA GAIN									
			x1		x2		x4		x8		x12	
			DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB	DYNAMIC RANGE (dB)	ENOB
000	64	16768	74.7	12.41	74.7	12.41	74.7	12.41	74.7	12.41	74.6	12.39
001	32	8384	90.3	15.01	90.3	15.00	90.2	14.99	89.9	14.93	89.4	14.85
010	16	4192	104.3	17.33	104	17.28	103.1	17.12	100.5	16.70	98.1	16.3
011	8	2096	112.3	18.7	111.6	18.6	109.7	18.3	106.3	17.7	103.8	17.3
100	4	1048	116	19.3	115.2	19.2	113.1	18.8	109.5	18.3	106.9	17.8
101	2	524	119.1	19.8	118.2	19.7	116.2	19.4	112.6	18.8	109.9	18.3
110	1	262	122.1	20.4	121.3	20.2	119.1	19.9	115.6	19.3	112.9	18.8



## 9 Detailed Description

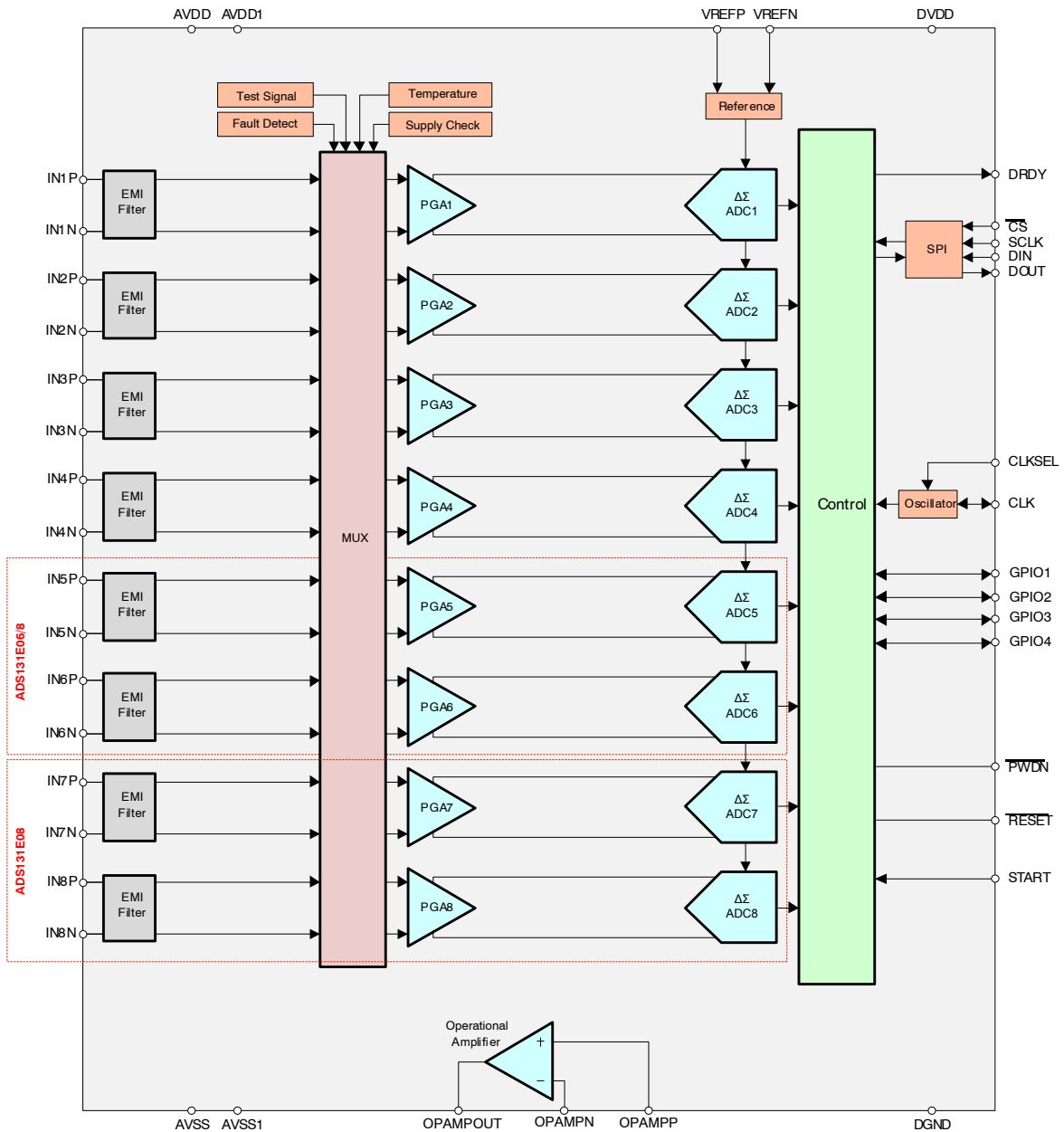
### 9.1 Overview

The ADS131E0x series are low-power, multichannel, simultaneously-sampling, 24-bit, delta-sigma ( $\Delta\Sigma$ ), analog-to-digital converter (ADC) with an integrated programmable gain amplifier (PGA). The analog device performance across a scalable data rate makes the device well-suited for smart-grid and other industrial power monitor, control, and protection applications.

The ADS131E0x devices have a programmable multiplexer that allows for various internal monitoring signal measurements including temperature, supply, and input-short for device noise testing. The PGA gain can be chosen from one of five settings: 1, 2, 4, 8, or 12. The ADCs in the device offer data rates of 1 kSPS, 2 kSPS, 4 kSPS, 8 kSPS, 16 kSPS, 32 kSPS, and 64 kSPS. The devices communicate using a serial peripheral interface (SPI)-compatible interface. The devices provide four general-purpose I/O (GPIO) pins for general use. Use multiple devices to easily add channels to the system and synchronize them with the START pins.

Program the internal reference to either 2.4 V or 4 V. The internal oscillator generates a 2.048-MHz clock. Use the integrated comparators, with programmable trigger-points, for input overrange or underrange detection. A detailed diagram of the ADS131E0x is provided in .

## 9.2 Functional Block Diagram



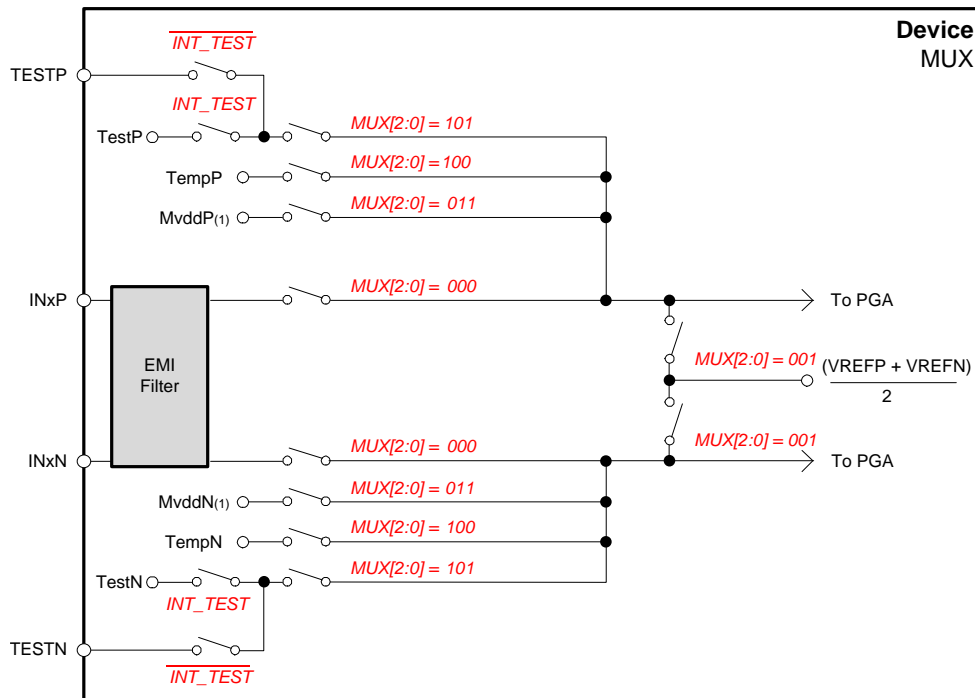
### 9.3 Feature Description

#### 9.3.1 Electromagnetic Interference (EMI) Filter

An RC filter at the input functions as an EMI filter on all channels. The –3-dB filter bandwidth is approximately 3 MHz.

#### 9.3.2 Input Multiplexer

The ADS131E0x input multiplexers are very flexible and provide many configurable signal-switching options. Figure 16 shows a diagram of the multiplexer on a single channel of the device. INxP and INxN are separate for each of the four, six or eight blocks (depending on device). This flexibility allows for significant device and sub-system diagnostics, calibration, and configuration. Switch settings for each channel are selected by writing the appropriate values to the CHnSET registers (see the CHnSET registers in the Register Map section for details). The output of each multiplexer is connected to the individual channel PGA.



- (1) MVDD monitor voltage supply depends on channel number; see the [Power-Supply Measurements \(MVDDP, MVDDN\)](#) section.

Figure 16. Input Multiplexer Block for One Channel

## Feature Description (continued)

### 9.3.2.1 Device Noise Measurements

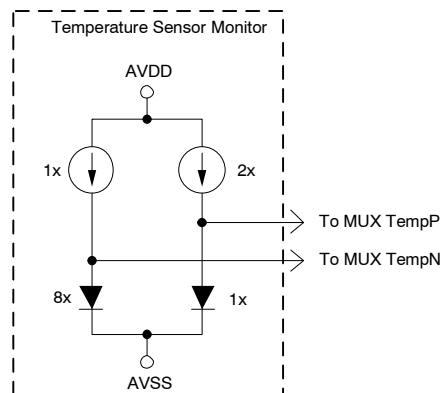
Setting CHnSET[2:0] = 001 sets the common-mode voltage of  $[(V_{VREFP} + V_{VREFN}) / 2]$  to both channel inputs. Use this setting to test inherent device noise in the user system.

### 9.3.2.2 Test Signals (TestP and TestN)

Setting CHnSET[2:0] = 101 provides internally-generated test signals for use in sub-system verification at power-up. The test signals are controlled through register settings (see the [CONFIG2: Configuration Register 2](#) section for details). TEST\_AMP controls the signal amplitude and TEST\_FREQ controls the switching frequency of the test signal. The test signals are multiplexed and transmitted out of the device at the TESTP and TESTN pins. The INT\_TEST register bit (in the [CONFIG2: Configuration Register 2](#) section) deactivates the internal test signals so that the test signal can be driven externally. This feature allows the test or calibration of multiple devices with the same signal.

### 9.3.2.3 Temperature Sensor (TempP, TempN)

Setting CHnSET[2:0] = 100 sets the channel input to the temperature sensor. This sensor uses two internal diodes with one diode having a current density 16 times that of the other, as shown in [Figure 17](#). The difference in diode current densities yields a difference in voltage that is proportional to absolute temperature.



**Figure 17. Temperature Sensor Implementation**

The internal device temperature tracks the PCB temperature closely because of the low thermal resistance of the package to the PCB. Self-heating of the ADS131E0x causes a higher reading than the temperature of the surrounding PCB. Setting the channel gain to 1 is recommended when the temperature measurement is taken.

The scale factor of [Equation 3](#) converts the temperature reading to °C. Before using this equation, the temperature reading code must first be scaled to  $\mu\text{V}$ .

$$\text{Temperature (}^\circ\text{C)} = \left[ \frac{\text{Temperature Reading (}\mu\text{V)} - 145,300 \mu\text{V}}{490 \mu\text{V}/^\circ\text{C}} \right] + 25^\circ\text{C} \quad (3)$$

### 9.3.2.4 Power-Supply Measurements (MVDDP, MVDDN)

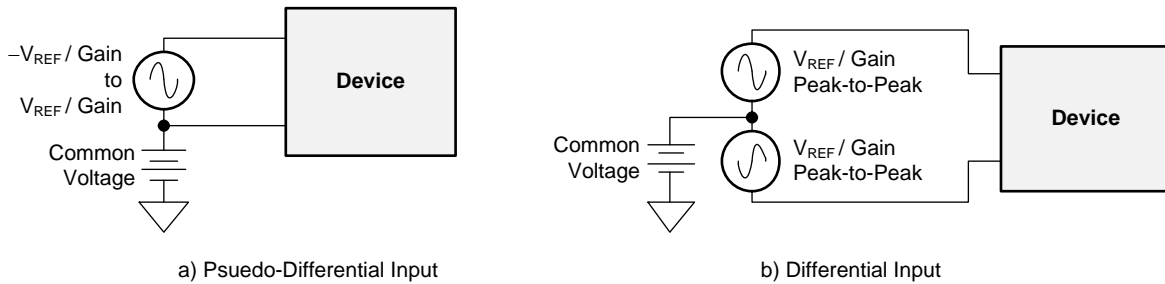
Setting CHnSET[2:0] = 011 sets the channel inputs to different device supply voltages. For channels 1, 2, 5, 6, 7, and 8 (MVDDP – MVDDN) is  $[0.5 \times (AVDD - AVSS)]$ ; for channels 3 and 4 (MVDDP – MVDDN) is DVDD / 4. Set the gain to 1 to avoid saturating the PGA when measuring power supplies.

## Feature Description (continued)

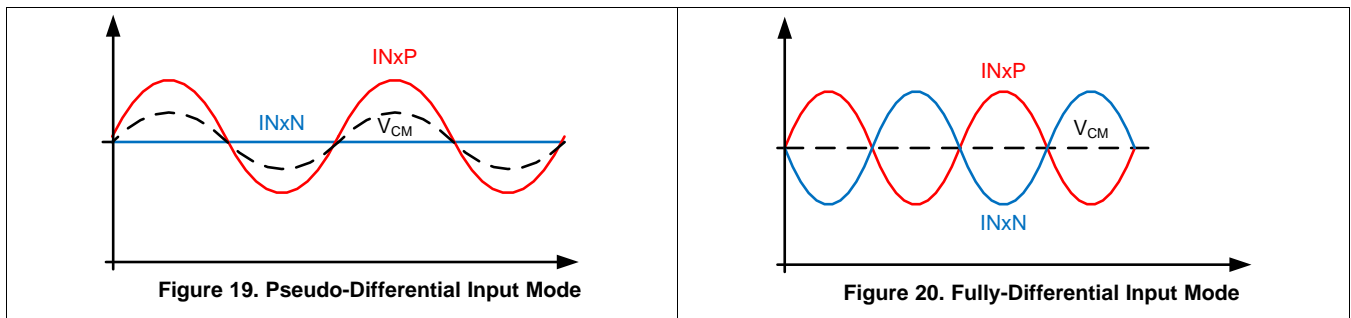
### 9.3.3 Analog Input

The analog inputs to the device connect directly to an integrated low-noise, low-drift, high input impedance, programmable gain amplifier. The amplifier is located following the individual channel multiplexer.

The ADS131E0x analog inputs are fully differential. The differential input voltage ( $V_{INXP} - V_{INXN}$ ) can span from  $-V_{REF} / \text{gain}$  to  $V_{REF} / \text{gain}$ . See the [Data Format](#) section for an explanation of the correlation between the analog input and digital codes. There are two general methods of driving the ADS131E0x analog inputs: pseudo-differential or fully-differential, as shown in [Figure 18](#), [Figure 19](#), and [Figure 20](#).



**Figure 18. Methods of Driving the ADS131E0x: Pseudo-Differential or Fully Differential**



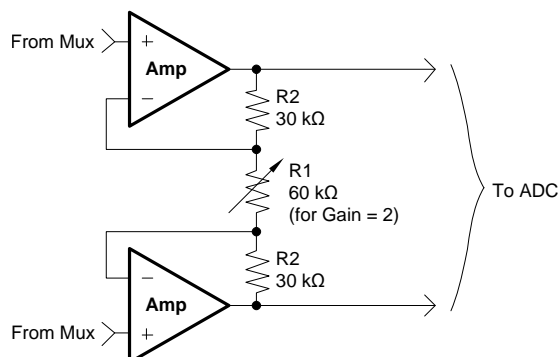
Hold the INxN pin at a common voltage, preferably at mid supply, to configure the fully differential input for a pseudo-differential signal. Swing the INxP pin around the common voltage  $-V_{REF} / \text{gain}$  to  $V_{REF} / \text{gain}$  and remain within the absolute maximum specifications. Verify that the differential signal at the minimum and maximum points meets the common-mode input specification discussed in the [Input Common-Mode Range](#) section.

Configure the signals at INxP and INxN to be  $180^\circ$  out-of-phase centered around a common-mode voltage,  $V_{CM}$ , to use a fully-differential input method. Both the INxP and INxN inputs swing from the  $V_{CM} + \frac{1}{2} V_{REF} / \text{gain}$  to the  $V_{CM} - \frac{1}{2} V_{REF} / \text{gain}$ . The differential voltage at the maximum and minimum points is equal to  $-V_{REF} / \text{gain}$  to  $V_{REF} / \text{gain}$ . Use the ADS131E0x in a differential configuration to maximize the dynamic range of the data converter. For optimal performance, the common-mode voltage is recommended to be set at the midpoint of the analog supplies  $[(AVDD + AVSS) / 2]$ .

If any of the analog input channels are not used, then power-down these pins using register bits to conserve power. See the [SPI Command Definitions](#) section for more information on how to power-down individual channels. Tie any unused or powered down analog input pins directly to AVDD.

### 9.3.4 PGA Settings and Input Range

Each channel has its own configurable programmable gain amplifier (PGA) following its multiplexer. The PGA is designed using two operational amplifiers in a differential configuration, as shown in [Figure 21](#). Set the gain to one of five settings (1, 2, 4, 8, and 12) using the CHnSET registers for each individual channel (see the [CHnSET](#) registers in the [Register Map](#) section for details). The ADS131E0x has CMOS inputs and therefore has negligible current noise. [Table 3](#) shows the typical small-signal bandwidth values for various gain settings.



**Figure 21. PGA Implementation**

**Table 3. PGA Gain versus Bandwidth**

GAIN	NOMINAL BANDWIDTH AT T <sub>A</sub> = 25°C (kHz)
1	237
2	146
4	96
8	48
12	32

The PGA resistor string that implements the gain has 120 kΩ of resistance for a gain of 2. This resistance provides a current path across the PGA outputs in the presence of a differential input signal. This current is in addition to the quiescent current specified for the device in the presence of a differential signal at the input.

### 9.3.4.1 Input Common-Mode Range

The usable input common-mode range of the analog front-end depends on various parameters, including the maximum differential input signal, supply voltage, and PGA gain. The common-mode range,  $V_{CM}$ , is defined in Equation 4:

$$AVDD - 0.3\text{ V} - \left[ \frac{\text{Gain} \times V_{\text{MAX\_DIFF}}}{2} \right] > V_{\text{CM}} > AVSS + 0.3\text{ V} + \left[ \frac{\text{Gain} \times V_{\text{MAX\_DIFF}}}{2} \right]$$

where:

- $V_{\text{MAX\_DIFF}}$  = maximum differential signal at the PGA input and
- $V_{\text{CM}}$  = common-mode voltage

(4)

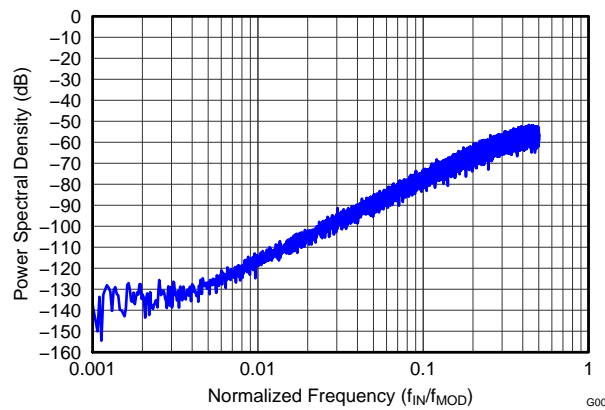
For example:

If  $AVDD - AVSS = 3.3\text{ V}$ , gain = 2, and  $V_{\text{MAX\_DIFF}} = 1000\text{ mV}$ ,

Then  $1.3\text{ V} < V_{\text{CM}} < 2.0\text{ V}$

### 9.3.5 $\Delta\Sigma$ Modulator

Each ADS131E0x channel has its own delta-sigma ( $\Delta\Sigma$ ) ADC. The  $\Delta\Sigma$  converters use second-order modulators optimized for low-power applications. The modulator samples the input signal at the modulator rate of ( $f_{\text{MOD}} = f_{\text{CLK}} / 2$ ). As with any  $\Delta\Sigma$  modulator, the ADS131E0x noise is shaped until  $f_{\text{MOD}} / 2$ , as shown in Figure 22.



**Figure 22. Modulator Noise Spectrum Up to  $0.5 \times f_{\text{MOD}}$**

### 9.3.6 Clock

The ADS131E0x provides two different device clocking methods: internal and external. Internal clocking using the internal oscillator is ideally-suited for non-synchronized, low-power systems. The internal oscillator is trimmed for accuracy at room temperature. The accuracy of the internal oscillator varies over the specified temperature range; see the [Electrical Characteristics](#) table for details. External clocking is recommended when synchronizing multiple ADS131E0x devices or when synchronizing to an external event because the internal oscillator clock performance can vary over temperature. Clock selection is controlled by the CLKSEL pin and the CLK\_EN register bit. Provide the external clock any time after the analog and digital supplies are present.

The CLKSEL pin selects either the internal oscillator or external clock. The CLK\_EN bit in the CONFIG1 register enables and disables the oscillator clock to be output on the CLK pin. A truth table for the CLKSEL pin and the CLK\_EN bit is shown in [Table 4](#). The CLK\_EN bit is useful when multiple devices are used in a daisy-chain configuration. During power-down, the external clock is recommended to be shut down to save power.

**Table 4. CLKSEL Pin and CLK\_EN Bit**

CLKSEL PIN	CLK_EN BIT	CLOCK SOURCE	CLK PIN STATUS
0	X	External clock	Input: external clock
1	0	Internal oscillator	3-state
1	1	Internal oscillator	Output: internal oscillator

### 9.3.7 Digital Decimation Filter

The digital filter receives the modulator output bit stream and decimates the data stream. The decimation ratio determines the number of samples taken to create the output data word, and is set by the modulator rate divided by the data rate ( $f_{MOD} / f_{DR}$ ). By adjusting the decimation ratio, a tradeoff can be made between resolution and data rate: higher decimation allows for higher resolution (thus creating lower data rates) and lower decimation decreases resolution but enables wider bandwidths with higher data rates. Higher data rates are typically used in power applications that implement software re-sampling techniques to help with channel-to-channel phase adjustment for voltage and current.

The digital filter on each channel consists of a third-order sinc filter. An input step change takes three conversion cycles for the filter to settle. Adjust the decimation ratio of the sinc<sup>3</sup> filters using the DR[2:0] bits in the CONFIG1 register (see the [Register Map](#) section for details). The data rate setting is a global setting that sets all channels to the same data rate.

The sinc filter is a variable decimation rate, third-order, low-pass filter. Data are supplied to this section of the filter from the modulator at the rate of  $f_{MOD}$ . The sinc<sup>3</sup> filter attenuates the high-frequency modulator noise, then decimates the data stream into parallel data. The decimation rate affects the overall converter data rate.

[Equation 5](#) shows the scaled sinc<sup>3</sup> filter Z-domain transfer function.

$$|H(z)| = \left| \frac{1 - Z^{-N}}{1 - Z^{-1}} \right|^3 \quad (5)$$

The sinc<sup>3</sup> filter frequency domain transfer function is shown in [Equation 6](#).

$$|H(f)| = \left| \frac{\sin \left[ \frac{N\pi f}{f_{MOD}} \right]}{N \times \sin \left[ \frac{\pi f}{f_{MOD}} \right]} \right|^3$$

where:

- N = decimation ratio (6)

The sinc<sup>3</sup> filter has notches (or zeroes) that occur at the output data rate and multiples thereof. At these frequencies, the filter has infinite attenuation. [Figure 23](#) illustrates the sinc filter frequency response and [Figure 24](#) illustrates the sinc filter roll-off. [Figure 25](#) and [Figure 26](#) illustrate the filter transfer function until  $f_{MOD} / 2$  and  $f_{MOD} / 16$ , respectively, at different data rates. [Figure 27](#) illustrates the transfer function extended until  $4 f_{MOD}$ . [Figure 27](#) illustrates that the ADS131E0x passband repeats itself at every  $f_{MOD}$ . Note that the digital filter response and filter notches are proportional to the master clock frequency.



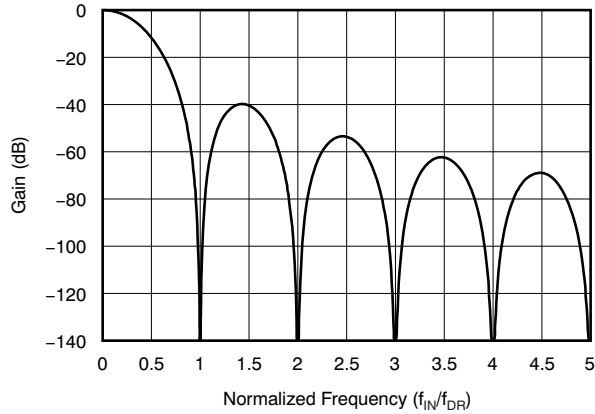


Figure 23. Sinc Filter Frequency Response

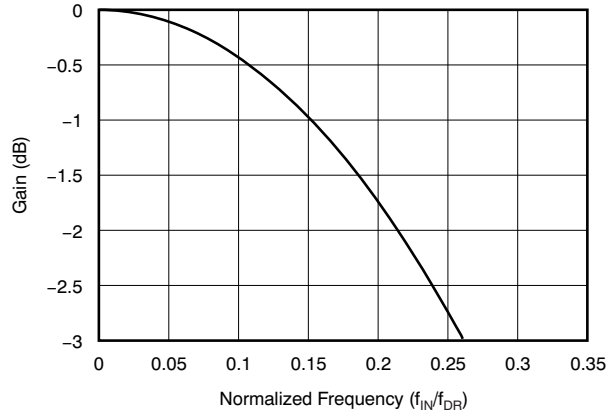


Figure 24. Sinc Filter Roll-Off

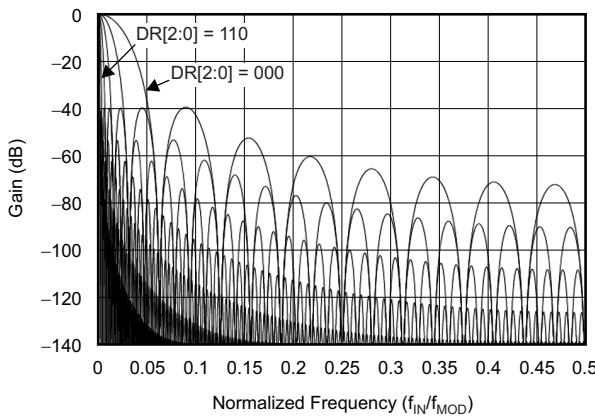


Figure 25. Transfer Function of Decimation Filters Until  $f_{MOD} / 2$

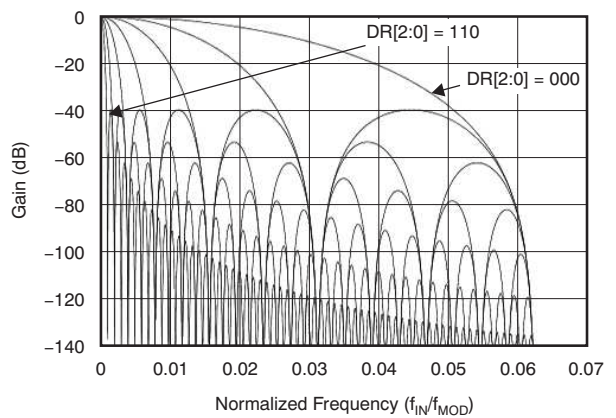


Figure 26. Transfer Function of Decimation Filters Until  $f_{MOD} / 16$

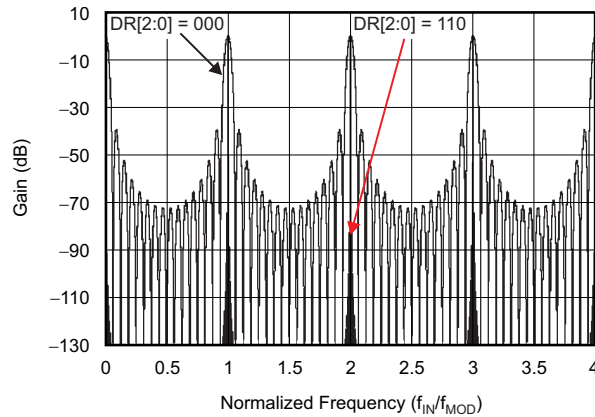
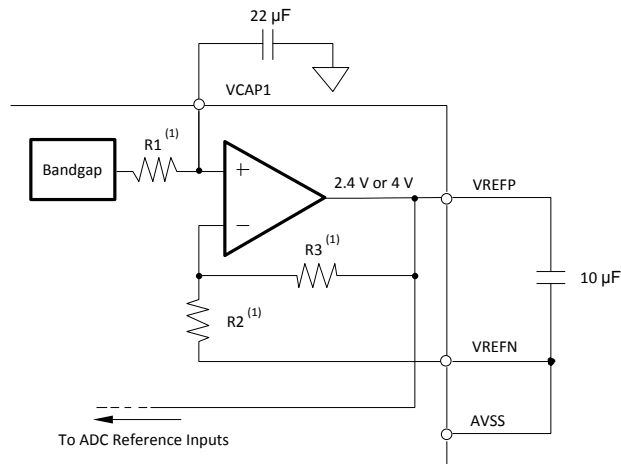


Figure 27. Transfer Function of Decimation Filters Until  $4 f_{MOD}$  for DR[2:0] = 000 and DR[2:0] = 110

### 9.3.8 Voltage Reference

Figure 28 shows a simplified block diagram of the internal ADS131E0x reference. The reference voltage is generated with respect to AVSS. When using the internal voltage reference, connect VREFN to AVSS.



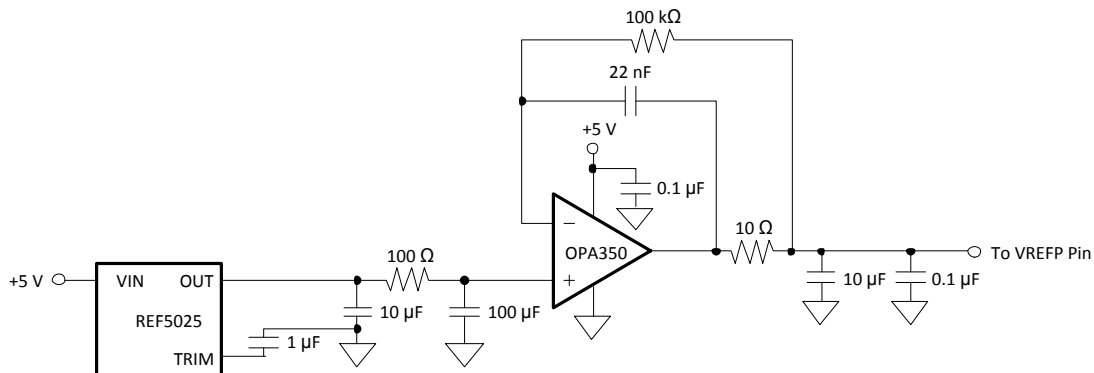
For  $V_{REF} = 2.4\text{ V}$ :  $R_1 = 12.5\text{ k}\Omega$ ,  $R_2 = 25\text{ k}\Omega$ , and  $R_3 = 25\text{ k}\Omega$ .

For  $V_{REF} = 4\text{ V}$ :  $R_1 = 10.5\text{ k}\Omega$ ,  $R_2 = 15\text{ k}\Omega$ , and  $R_3 = 35\text{ k}\Omega$ .

**Figure 28. Internal Reference**

The external band-limiting capacitors determine the amount of reference noise contribution. For high-end systems, the capacitor values should be chosen such that the bandwidth is limited to less than 10 Hz, so that the reference noise does not dominate the system noise. When using a 3-V analog supply, the internal reference must be set to 2.4 V. In case of a 5-V analog supply, the internal reference can be set to 4 V by setting the VREF\_4V bit in the CONFIG2 register.

Alternatively, the internal reference buffer can be powered down and VREFP can be driven externally. Figure 29 shows a typical external reference drive circuit. Power-down is controlled by the PD\_REFBUF bit in the CONFIG3 register. This power-down is also used to share internal references when two devices are cascaded. By default, the device wakes up in external reference mode.



**Figure 29. External Reference Driver**

### 9.3.9 Input Out-of-Range Detection

The ADS131E0x has integrated comparators to detect out-of-range conditions on the input signals. The basic principle is to compare the input voltage against a threshold voltage set by a 3-bit digital-to-analog converter (DAC) based off the analog power supply. The comparator trigger threshold level is set by the COMP\_TH[2:0] bits in the FAULT register.

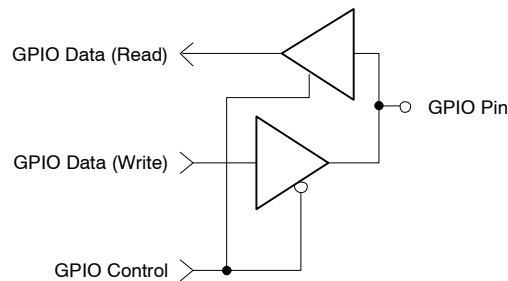
If the ADS131E0x is powered from a  $\pm 2.5$ -V supply and COMP\_TH[2:0] = 000 (95% and 5%), the high-side trigger threshold is set at 2.25 V [equal to  $AVSS + (AVDD - AVSS) \times 95\%$ ] and the low-side threshold is set at  $-2.25$  V [equal to  $AVSS + (AVDD - AVSS) \times 5\%$ ]. The threshold calculation formula applies to unipolar as well as to bipolar supplies.

A fault condition can be detected by setting the appropriate threshold level using the COMP\_TH[2:0] bits. To determine which of the inputs is out of range, read the FAULT\_STATP and FAULT\_STATN registers individually or read the FAULT\_STATx bits as part of the output data stream; see the [Data Output \(DOUT\)](#) section.

### 9.3.10 General-Purpose Digital I/O (GPIO)

The ADS131E0x has a total of four general-purpose digital I/O (GPIO) pins available. Configure the digital I/O pins as either inputs or outputs through the GPIOC bits. The GPIOD bits in the GPIO register indicate the level of the pins. The GPIO logic high voltage level is set by the voltage level of DVDD. When reading the GPIOD bits, the data returned are the logic level of the pins, whether they are programmed as inputs or outputs. When the GPIO pin is configured as an input, a write to the corresponding GPIOD bit has no effect. When configured as an output, a write to the GPIOD bit sets the output level.

If configured as inputs, the GPIO pins must be driven to a defined state. The GPIO pins are set as inputs after power up or after a reset. [Figure 30](#) shows the GPIO pin structure. Connect unused GPIO pins directly to DGND through 10-k $\Omega$  resistors.



**Figure 30. GPIO Pin Implementation**

## 9.4 Device Functional Modes

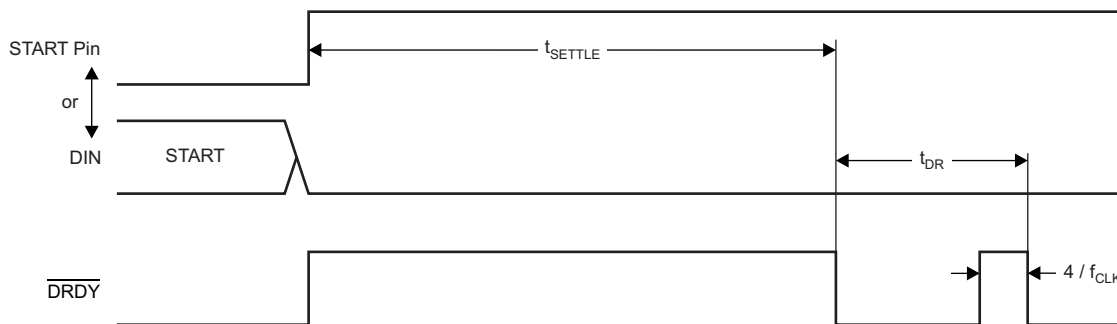
### 9.4.1 Start

Pull the START pin high for at least  $2 t_{CLK}$  periods, or send the START command to begin conversions. When START is low and the START command has not been sent, the device does not issue a  $\overline{DRDY}$  signal (conversions are halted).

When using the START command to control conversions, hold the START pin low. In multiple device configurations, the START pin is used to synchronize devices (see the [Multiple Device Configuration](#) subsection for more details).

#### 9.4.1.1 Settling Time

The settling time ( $t_{SETTLE}$ ) is the time required for the converter to output fully-settled data when the START signal is pulled high. When START is pulled high,  $\overline{DRDY}$  is also pulled high. The next  $\overline{DRDY}$  falling edge indicates that data are ready. [Figure 31](#) shows the timing diagram and [Table 5](#) shows the settling time for different data rates as a function of  $t_{CLK}$ . The settling time depends on  $f_{CLK}$  and the decimation ratio (controlled by the DR[2:0] bits in the CONFIG1 register). When the initial settling time has passed, the  $\overline{DRDY}$  falling edge occurs at the set data rate,  $t_{DR}$ . If data is not read back on DOUT and the output shift register needs to update,  $\overline{DRDY}$  goes high for  $4 t_{CLK}$  before returning back low indicating new data is ready. Note that when START is held high and there is a step change in the input signal,  $3 \times t_{DR}$  is required for the filter to settle to the new value. Settled data are available on the fourth  $\overline{DRDY}$  pulse.



**Figure 31. Settling Time**

**Table 5. Settling Time for Different Data Rates**

DR[2:0]	NORMAL MODE	UNIT
000	152	$t_{CLK}$
001	296	$t_{CLK}$
010	584	$t_{CLK}$
011	1160	$t_{CLK}$
100	2312	$t_{CLK}$
101	4616	$t_{CLK}$
110	9224	$t_{CLK}$

#### 9.4.1.2 Input Signal Step

When the device is converting and there is a step change on the input signal, a delay of  $3 t_{DR}$  is required for the output data to settle. Settled data are available on the fourth  $\overline{DRDY}$  pulse. Data are available to read at each  $\overline{DRDY}$  low transition prior to the 4th  $\overline{DRDY}$  pulse, but are recommended to be ignored. [Figure 32](#) shows the required wait time for complete settling for an input step or input transient event on the analog input.

## Device Functional Modes (continued)

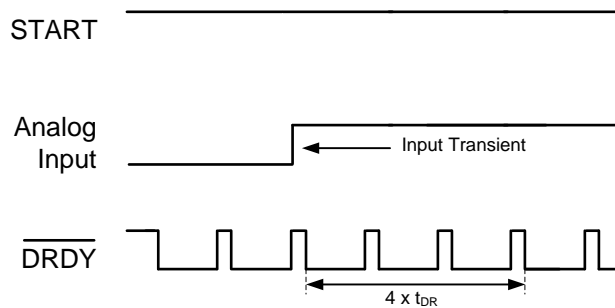


Figure 32. Settling Time for the Input Transient

### 9.4.2 Reset ( $\overline{\text{RESET}}$ )

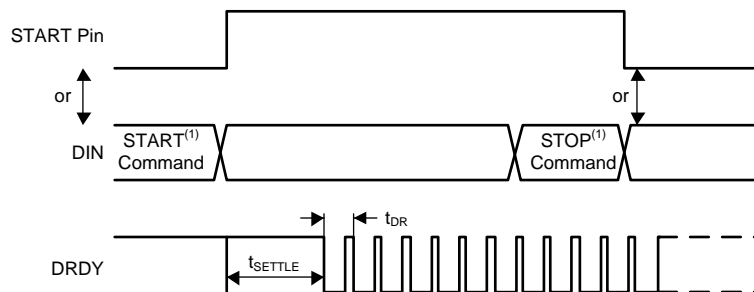
There are two methods to reset the ADS131E0x: pull the  $\overline{\text{RESET}}$  pin low, or send the RESET command. When using the  $\overline{\text{RESET}}$  pin, make sure to follow the minimum pulse duration timing specifications before taking the pin back high. The RESET command takes effect on the eighth SCLK falling edge of the command. After a reset, 18  $t_{\text{CLK}}$  cycles are required to complete initialization of the configuration registers to default states and start the conversion cycle. Note that an internal reset is automatically issued to the digital filter whenever the CONFIG1 register is set to a new value with a WREG command.

### 9.4.3 Power-Down ( $\overline{\text{PWDN}}$ )

When  $\overline{\text{PWDN}}$  is pulled low, all on-chip circuitry is powered down. To exit power-down mode, take the  $\overline{\text{PWDN}}$  pin high. Upon exiting from power-down mode, the internal oscillator and the reference require time to wake up. During power-down, the external clock is recommended to be shut down to save power.

### 9.4.4 Continuous Conversion Mode

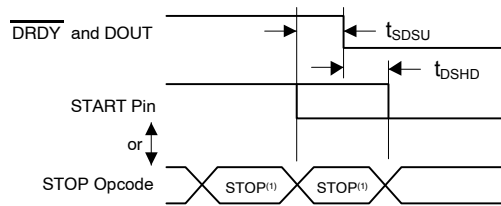
Conversions begin when the START pin is taken high or when the START command is sent. As shown in Figure 33, the DRDY output goes high when conversions are started and goes low when data are ready. Conversions continue indefinitely until the START pin is taken low or the STOP command is transmitted. When the START pin is pulled low or the STOP command is issued, the conversion in progress is allowed to complete. Figure 34 and Table 6 show the required DRDY timing to the START pin or the START and STOP commands when controlling conversions in this mode. The  $t_{\text{SDSU}}$  timing indicates when to take the START pin low or when to send the STOP command before the DRDY falling edge to halt further conversions. The  $t_{\text{DSDH}}$  timing indicates when to take the START pin low or send the STOP command after a DRDY falling edge to complete the current conversion and halt further conversions. To keep the converter running continuously, the START pin can be permanently tied high.



(1) START and STOP commands take effect on the seventh SCLK falling edge.

Figure 33. Continuous Conversion Mode

**Device Functional Modes (continued)**



(1) START and STOP commands take effect on the seventh SCLK falling edge at the end of the transmission.

**Figure 34. START to  $\overline{\text{DRDY}}$  Timing**

**Table 6. Timing Characteristics for Figure 34<sup>(1)</sup>**

		MIN	UNIT
$t_{\text{SDSU}}$	Setup time: START pin low or STOP command before the $\overline{\text{DRDY}}$ falling edge to halt further conversions	16	$t_{\text{CLK}}$
$t_{\text{DSDH}}$	Delay time: START pin low or STOP command to complete the current conversion and halt further conversions	16	$t_{\text{CLK}}$

(1) START and STOP commands take effect on the seventh SCLK falling edge at the end of the transmission.

**9.4.5 Data Retrieval**

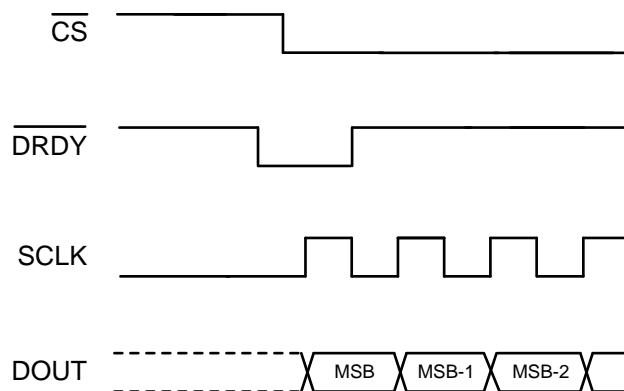
**9.4.5.1 Data Ready ( $\overline{\text{DRDY}}$ )**

$\overline{\text{DRDY}}$  is an output signal which transitions from high to low indicating new conversion data are ready. The  $\overline{\text{CS}}$  signal has no effect on the data ready signal.  $\overline{\text{DRDY}}$  behavior is determined by whether the device is in RDATA mode or the RDATA command is used to read data on demand. (See the [RDATA: Start Read Data Continuous Mode](#) and [RDATA: Read Data](#) subsections of the [SPI Command Definitions](#) section for further details).

When reading data with the RDATA command, the read operation can overlap the next  $\overline{\text{DRDY}}$  occurrence without data corruption.

The START pin or the START command places the device either in normal data capture mode or pulse data capture mode.

Figure 35 shows the relationship between  $\overline{\text{CS}}$ ,  $\overline{\text{DRDY}}$ , DOUT, and SCLK during data retrieval (in case of an ADS131E0x). DOUT is latched out at the SCLK rising edge.  $\overline{\text{DRDY}}$  is pulled high at the SCLK falling edge. Note that  $\overline{\text{DRDY}}$  goes high on the first SCLK falling edge, regardless of whether data are being retrieved from the device or a command is being sent through the DIN pin.



**Figure 35.  $\overline{\text{DRDY}}$  Behavior with Data Retrieval**

The  $\overline{\text{DRDY}}$  signal is cleared on the first SCLK falling edge regardless of the state of  $\overline{\text{CS}}$ . This condition must be taken into consideration if the SPI bus is used to communicate with other devices on the same bus. Figure 36 shows a behavior diagram for  $\overline{\text{DRDY}}$  when SCLKs are sent with  $\overline{\text{CS}}$  high. Figure 36 shows that no data are clocked out, but the  $\overline{\text{DRDY}}$  signal is cleared.

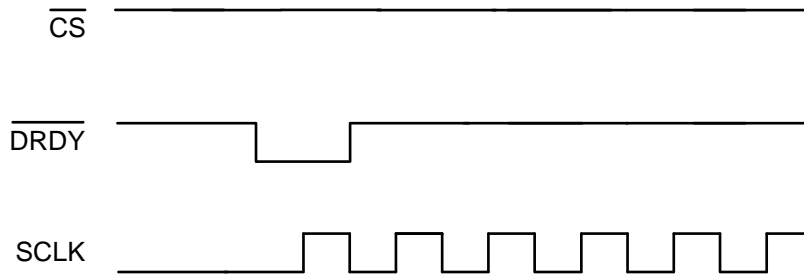


Figure 36.  $\overline{\text{DRDY}}$  and SCLK Behavior when  $\overline{\text{CS}}$  is High

#### 9.4.5.2 Reading Back Data

Data retrieval can be accomplished in one of two methods:

1. RDATA: the read data command requires that a command is sent to the device to load the output shift register with the latest data. See the [RDATA: Read Data](#) section for more details.
2. RDATA: the read data continuous command sets the device in a mode that reads data continuously without sending commands. See the [RDATA: Start Read Data Continuous Mode](#) section for more details.

Conversion data are read by shifting data out on DOUT. The MSB of the data on DOUT is clocked out on the first SCLK rising edge.  $\overline{\text{DRDY}}$  returns high on the first SCLK falling edge. DIN should remain low for the entire read operation.

#### 9.4.5.3 Status Word

A status word precedes data readback and provides information on the state of the ADS131E0x. The status word is 24 bits long and contains the values for FAULT\_STATP, FAULT\_STATN, and the GPIO data bits. The content alignment is shown in Figure 37.

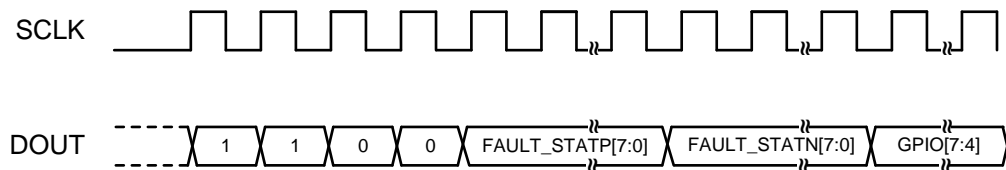


Figure 37. Status Word Content

#### NOTE

The status word length is always 24 bits. The length does not change for 32-kSPS and 64-kSPS data rates.

#### 9.4.5.4 Readback Length

The number of bits in the data output depends on the number of channels and the number of bits per channel. The data format for each channel data are two's complement and MSB first.

For the ADS131E0x with 32-kSPS and 64-kSPS data rates, the number of data bits is: 24 status bits + 16 bits per channel × 8 channels = 152 bits.

For all other data rates, the number of data bits is: 24 status bits + 24 bits per channel × 8 channels = 216 bits.

When channels are powered down using the user register setting, the corresponding channel output is set to 0. However, the sequence of channel outputs remains the same.

The ADS131E0x also provides a multiple data readback feature. Data can be read out multiple times by simply providing more SCLKs, in which case the MSB data byte repeats after reading the last byte. The DAISY\_IN bit in the CONFIG1 register must be set to 1 for multiple read backs.



## 9.5 Programming

### 9.5.1 Data Format

The DR[2:0] bits in the CONFIG1 register sets the output resolution for the ADS131E0x. When DR[2:0] = 000 or 001, the 16 bits of data per channel are sent in binary twos complement format, MSB first. The size of one code (LSB) is calculated using [Equation 7](#).

$$1 \text{ LSB} = (2 \times V_{\text{REF}} / \text{Gain}) / 2^{16} = \text{FS} / 2^{15} \quad (7)$$

A positive full-scale input [ $V_{\text{IN}} \geq (\text{FS} - 1 \text{ LSB}) = (V_{\text{REF}} / \text{Gain} - 1 \text{ LSB})$ ] produces an output code of 7FFFh and a negative full-scale input ( $V_{\text{IN}} \leq -\text{FS} = -V_{\text{REF}} / \text{Gain}$ ) produces an output code of 8000h. The output clips at these codes for signals that exceed full-scale.

[Table 7](#) summarizes the ideal output codes for different input signals.

**Table 7. 16-Bit Ideal Output Code versus Input Signal**

INPUT SIGNAL, $V_{\text{IN}}$ $V_{(\text{IN} \times \text{P})} - V_{(\text{IN} \times \text{N})}$	IDEAL OUTPUT CODE <sup>(1)</sup>
$\geq \text{FS} (2^{15} - 1) / 2^{15}$	7FFFh
$\text{FS} / 2^{15}$	0001h
0	0000h
$-\text{FS} / 2^{15}$	FFFFh
$\leq -\text{FS}$	8000h

(1) Excludes the effects of noise, INL, offset, and gain errors.

When DR[2:0] = 010, 011, 100, 101, or 110, the ADS131E0x outputs 24 bits of data per channel in binary twos complement format, MSB first. The size of one code (LSB) is calculated using [Equation 8](#).

$$1 \text{ LSB} = (2 \times V_{\text{REF}} / \text{Gain}) / 2^{24} = \text{FS} / 2^{23} \quad (8)$$

A positive full-scale input [ $V_{\text{IN}} \geq (\text{FS} - 1 \text{ LSB}) = (V_{\text{REF}} / \text{Gain} - 1 \text{ LSB})$ ] produces an output code of 7FFFFFFh and a negative full-scale input ( $V_{\text{IN}} \leq -\text{FS} = -V_{\text{REF}} / \text{Gain}$ ) produces an output code of 800000h. The output clips at these codes for signals that exceed full-scale.

[Table 8](#) summarizes the ideal output codes for different input signals.

**Table 8. 24-Bit Ideal Output Code versus Input Signal**

INPUT SIGNAL, $V_{\text{IN}}$ $V_{(\text{IN} \times \text{P})} - V_{(\text{IN} \times \text{N})}$	IDEAL OUTPUT CODE <sup>(1)</sup>
$\geq \text{FS} (2^{23} - 1) / 2^{23}$	7FFFFFFh
$\text{FS} / 2^{23}$	000001h
0	000000h
$-\text{FS} / 2^{23}$	FFFFFFh
$\leq -\text{FS}$	800000h

(1) Excludes the effects of noise, INL, offset, and gain errors.

### 9.5.2 SPI Interface

The SPI-compatible serial interface consists of four signals:  $\overline{\text{CS}}$ , SCLK, DIN, and DOUT. The interface is used to read conversion data, read and write registers, and control the ADS131E0x operation. The  $\overline{\text{DRDY}}$  output is used as a status signal to indicate when ADC data are ready for readback.  $\overline{\text{DRDY}}$  goes low when new data are available.

#### 9.5.2.1 Chip Select ( $\overline{\text{CS}}$ )

The  $\overline{\text{CS}}$  pin activates SPI communication.  $\overline{\text{CS}}$  must be low before data transactions and must stay low for the entire SPI communication period. When  $\overline{\text{CS}}$  is high, the DOUT pin enters a high-impedance state. Therefore, reading and writing to the serial interface are ignored and the serial interface is reset.  $\overline{\text{DRDY}}$  pin operation is independent of CS. DRDY still indicates that a new conversion has completed and is forced high as a response to SCLK, even if CS is high.

Taking  $\overline{CS}$  high deactivates only the SPI communication with the device and the serial interface is reset. Data conversion continues and the  $\overline{DRDY}$  signal can be monitored to check if a new conversion result is ready. A master device monitoring the  $\overline{DRDY}$  signal can select the appropriate slave device by pulling the  $\overline{CS}$  pin low. After the serial communication is finished, always wait four or more  $t_{CLK}$  cycles before taking  $\overline{CS}$  high.

### 9.5.2.2 Serial Clock (SCLK)

SCLK provides the clock for serial communication. SCLK is a Schmitt-trigger input, but TI recommends keeping SCLK as free from noise as possible to prevent glitches from inadvertently shifting the data. Data are shifted into DIN on the falling edge of SCLK and shifted out of DOUT on the rising edge of SCLK.

The absolute maximum SCLK limit is specified in [Figure 1](#). When shifting in commands with SCLK, make sure that the entire set of SCLKs is issued to the device. Failure to do so can result in the device serial interface being placed into an unknown state requiring  $\overline{CS}$  to be taken high to recover.

For a single device, the minimum speed required for SCLK depends on the number of channels, number of bits of resolution, and output data rate. (For multiple devices, see the [Multiple Device Configuration](#) section.)

For example, if the ADS131E0x is used with an 8-kSPS mode (24-bit resolution), the minimum SCLK speed is 1.755 MHz to shift out all the data.

Data retrieval can be accomplished either by placing the device in RDATA mode or by issuing an RDATA command for data on demand. The SCLK rate limitation in [Equation 9](#) applies to RDATA. For the RDATA command, the limitation applies if data must be read in between two consecutive  $\overline{DRDY}$  signals. [Equation 9](#) assumes that there are no other commands issued in between data captures.

$$t_{SCLK} < (t_{DR} - 4 t_{CLK}) / (N_{BITS} \times 8 + 24)$$

where

- $N_{BITS}$  = resolution of data for the current data rate; 16 or 24 (9)

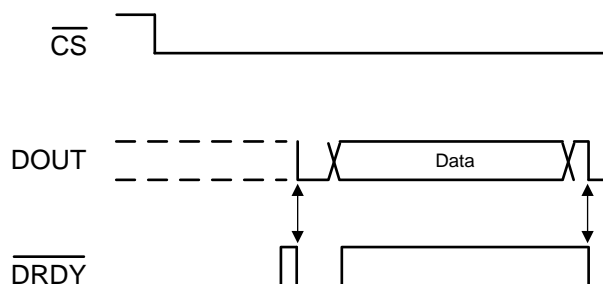
### 9.5.2.3 Data Input (DIN)

DIN is used along with SCLK to send data to the device. Data on DIN are shifted into the device on the falling edge of SCLK.

The communication of this device is full-duplex in nature. The device monitors commands shifted in even when data are being shifted out. Data that are present in the output shift register are shifted out when sending in a command. Therefore, make sure that whatever is being sent on the DIN pin is valid when shifting out data. When no command is to be sent to the device when reading out data, send the NOP command on DIN. Make sure that the  $t_{SDECODE}$  timing is met in the [Sending Multibyte Commands](#) section when sending multiple byte commands on DIN.

### 9.5.2.4 Data Output (DOUT)

DOUT is used with SCLK to read conversion and register data from the device. Data are clocked out on the rising edge of SCLK, MSB first. DOUT goes to a high-impedance state when  $\overline{CS}$  is high. In read data continuous mode (see the [SPI Command Definitions](#) section for more details), the DOUT output line can also be used to indicate when new data are available. If  $\overline{CS}$  is low when new data are ready, a high-to-low transition on the DOUT line occurs synchronously with a high-to-low transition on  $\overline{DRDY}$ , as shown in [Figure 38](#). This feature can be used to minimize the number of connections between the device and system controller.



**Figure 38. Using DOUT as  $\overline{DRDY}$**

### 9.5.3 SPI Command Definitions

The ADS131E0x provides flexible configuration control. The commands, summarized in [Table 9](#), control and configure device operation. The commands are stand-alone, except for the register read and register write operations that require a second command byte to include additional data.  $\overline{CS}$  can be taken high or held low between commands but must stay low for the entire command operation (including multibyte commands). System commands and the RDATA command are decoded by the ADS131E0x on the seventh SCLK falling edge. The register read and write commands are decoded on the eighth SCLK falling edge. Be sure to follow the SPI timing requirements when pulling  $\overline{CS}$  high after issuing a command.

**Table 9. Command Definitions**

COMMAND	DESCRIPTION	FIRST BYTE	SECOND BYTE
<b>SYSTEM COMMANDS</b>			
WAKEUP	Wake-up from standby mode	0000 0010 (02h)	
STANDBY	Enter standby mode	0000 0100 (04h)	
RESET	Reset the device	0000 0110 (06h)	
START	Start or restart (synchronize) conversions	0000 1000 (08h)	
STOP	Stop conversions	0000 1010 (0Ah)	
OFFSETCAL	Channel offset calibration	0001 1010 (1Ah)	
<b>DATA READ COMMANDS</b>			
RDATAC	Enable read data continuous mode. This mode is the default mode at power-up. <sup>(1)</sup>	0001 0000 (10h)	
SDATAC	Stop read data continuous mode	0001 0001 (11h)	
RDATA	Read data by command	0001 0010 (12h)	
<b>REGISTER READ COMMANDS</b>			
RREG	Read $n$ $nnnn$ registers starting at address $r$ $rrrr$	001 $r$ $rrrr$ (2xh) <sup>(2)</sup>	000 $n$ $nnnn$ <sup>(2)</sup>
WREG	Write $n$ $nnnn$ registers starting at address $r$ $rrrr$	010 $r$ $rrrr$ (4xh) <sup>(2)</sup>	000 $n$ $nnnn$ <sup>(2)</sup>

(1) When in RDATAC mode, the RREG command is ignored.

(2)  $n$   $nnnn$  = number of registers to be read or written – 1. For example, to read or write three registers, set  $n$   $nnnn$  = 0 (0010).  $r$   $rrrr$  = the starting register address for read and write commands.

#### 9.5.3.1 Sending Multibyte Commands

The ADS131E0x serial interface decodes commands in bytes and requires 4  $t_{CLK}$  cycles to decode and execute each command. Therefore, when sending multi-byte commands (such as RREG or WREG), a 4  $t_{CLK}$  period must separate the end of one byte (or command) and the next.

Assuming CLK is 2.048 MHz, then  $t_{SDECODE}$  (4  $t_{CLK}$ ) is 1.96  $\mu$ s. When SCLK is 16 MHz, one byte can be transferred in 0.5  $\mu$ s. This byte transfer time does not meet the  $t_{SDECODE}$  specification; therefore, a delay of 1.46  $\mu$ s (1.96  $\mu$ s – 0.5  $\mu$ s) must be inserted after the first byte and before the second byte. If SCLK is 4 MHz, one byte is transferred in 2  $\mu$ s. Because this transfer time exceeds the  $t_{SDECODE}$  specification (2  $\mu$ s > 1.96  $\mu$ s), the processor can send subsequent bytes without delay.

#### 9.5.3.2 WAKEUP: Exit STANDBY Mode

The WAKEUP command exits the low-power standby mode; see the [STANDBY: Enter STANDBY Mode](#) section. Be sure to allow enough time for all circuits in standby mode to power-up (see the [Electrical Characteristics](#) table for details). There are no SCLK rate restrictions for this command and it can be issued at any time. There are no SCLK rate restrictions for this command and can be issued at any time. Any following commands must be sent after a delay of 4  $t_{CLK}$  cycles.

#### 9.5.3.3 STANDBY: Enter STANDBY Mode

The STANDBY command enters low-power standby mode. All circuits in the device are powered down except for the reference section. The standby mode power consumption is specified in the [Electrical Characteristics](#) table. There are no SCLK rate restrictions for this command and can be issued at any time. Do not send any other commands other than the WAKEUP command after the device enters standby mode.

### 9.5.3.4 RESET: Reset Registers to Default Values

The RESET command resets the digital filter and returns all register settings to their default values; see the [Reset \(RESET\)](#) section for more details. There are no SCLK rate restrictions for this command and can be issued at any time. 18  $t_{CLK}$  cycles are required to execute the RESET command. Avoid sending any commands during this time.

### 9.5.3.5 START: Start Conversions

The START command starts data conversions. Tie the START pin low to control conversions by the START and STOP commands. If conversions are in progress, this command has no effect. The STOP command is used to stop conversions. If the START command is immediately followed by a STOP command, then there must be a gap of 4  $t_{CLK}$  cycle delay between them. The current conversion completes before further conversions are halted. There are no SCLK rate restrictions for this command and can be issued at any time.

### 9.5.3.6 STOP: Stop Conversions

The STOP command stops conversions. Tie the START pin low to control conversions by command. When the STOP command is sent, the conversion in progress completes and further conversions are stopped. If conversions are already stopped, this command has no effect. There are no SCLK rate restrictions for this command and can be issued at any time.

### 9.5.3.7 OFFSETCAL: Channel Offset Calibration

The OFFSETCAL command cancels the offset of each channel. The OFFSETCAL command is recommended to be issued every time there is a change in PGA gain settings.

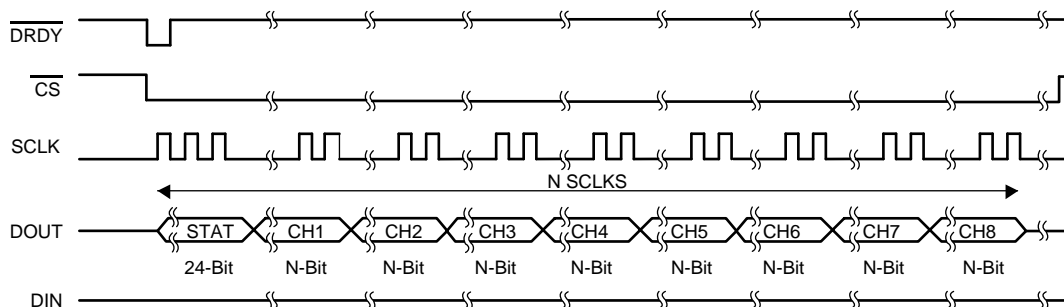
When the OFFSETCAL command is issued, the device configures itself to the lowest data rate ( $DR[2:0] = 110$ , 1 kSPS) and performs the following steps for each channel:

- Short the analog inputs of each channel together and connect them to mid-supply  $[(AVDD + AVSS) / 2]$
- Reset the digital filter (requires a filter settling time = 4  $t_{DR}$ )
- Collect 16 data points for calibration = 15  $t_{DR}$

Total calibration time =  $(19 t_{DR} \times 8) + 1 \text{ ms} = 153 \text{ ms}$ .

### 9.5.3.8 RDATA: Start Read Data Continuous Mode

The RDATA command enables read data continuous mode. In this mode, conversion data are retrieved from the device without the need to issue subsequent RDATA commands. This mode places the conversion data in the output register with every DRDY falling edge so that the data can be shifted out directly with the following SCLKs. Shift out all data from the device before data are updated with a new  $\overline{DRDY}$  falling edge to avoid losing data. The read data continuous mode is the device default mode; the device defaults to this mode on powerup. [Figure 39](#) shows the ADS131E0x data output protocol when using RDATA mode.



NOTE:  $X \text{ SCLKs} = (N \text{ bits})(8 \text{ channels}) + 24 \text{ bits}$ . N-bit is dependent upon the  $DR[2:0]$  registry bit settings ( $N = 16$  or  $24$ ).

**Figure 39. ADS131E0x SPI Bus Data Output (Eight Channels)**

RDATA mode is cancelled by the Stop Read Data Continuous command. If the device is in RDATA mode, a SDATAC command must be issued before any other commands can be sent to the device. There are no SCLK rate restrictions for this command. However, subsequent data retrieval SCLKs or the SDATAC command should wait at least  $4 t_{CLK}$  cycles before completion. RDATA timing is shown in Figure 40. There is a *keep out* zone of  $4 t_{CLK}$  cycles around the  $\overline{DRDY}$  pulse where this command cannot be issued in. If no data are retrieved from the device and  $\overline{CS}$  is held low, a high-to-low DOUT transition occurs synchronously with  $\overline{DRDY}$ . To retrieve data from the device after the RDATA command is issued, make sure either the START pin is high or the START command is issued. Figure 40 shows the recommended way to use the RDATA command. Read data continuous mode is ideally-suited for applications such as data loggers or recorders where registers are set one time and do not need to be reconfigured.

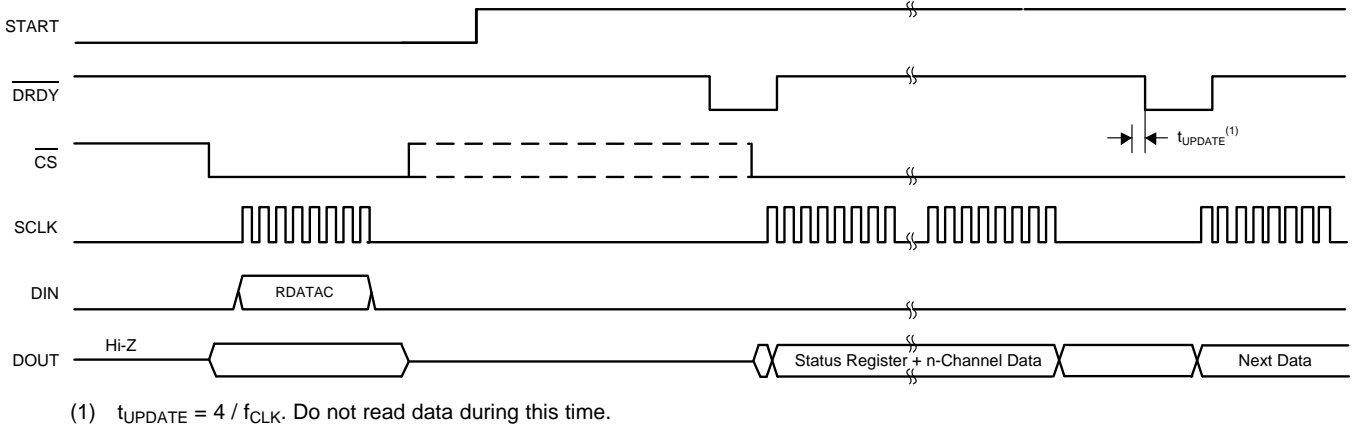


Figure 40. Reading Data in RDATA Mode

### 9.5.3.9 SDATAC: Stop Read Data Continuous Mode

The SDATAC command cancels the Read Data Continuous mode. There are no SCLK rate restrictions for this command, but the next command must wait for  $4 t_{CLK}$  cycles before completion.

### 9.5.3.10 RDATA: Read Data

The RDATA command loads the output shift register with the latest data when not in Read Data Continuous mode. Issue this command after  $\overline{DRDY}$  goes low to read the conversion result. There are no SCLK rate restrictions for this command, and there is no wait time needed for the subsequent commands or data retrieval SCLKs. To retrieve data from the device after the RDATA command is issued, make sure either the START pin is high or the START command is issued. When reading data with the RDATA command, the read operation can overlap the next  $\overline{DRDY}$  occurrence without data corruption. RDATA can be sent multiple times after new data are available, thus supporting multiple data readback. Figure 41 illustrates the recommended way to use the RDATA command. RDATA is best suited for systems where register settings must be read or the user does not have precise control over timing. Reading data using the RDATA command is recommended to avoid data corruption when the  $\overline{DRDY}$  signal is not monitored.

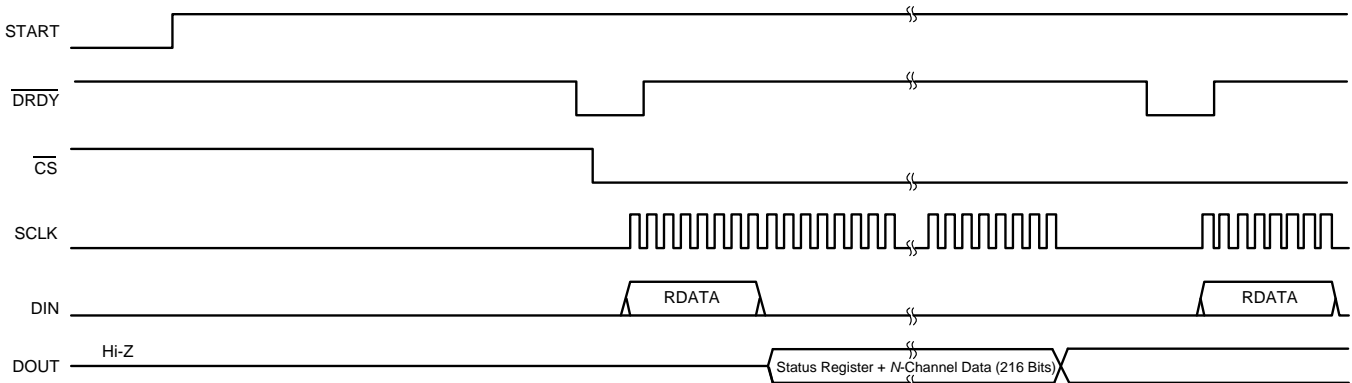


Figure 41. RDATA Usage

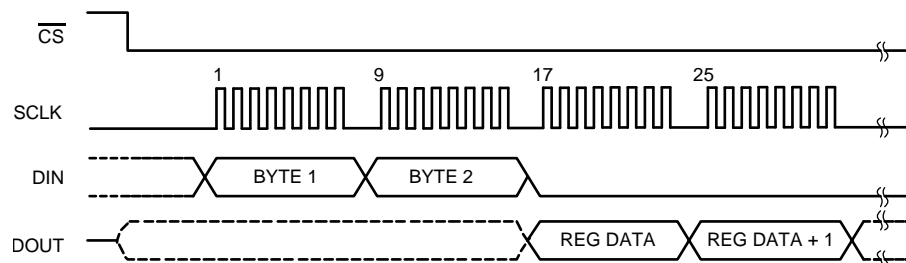
### 9.5.3.11 RREG: Read from Register

The RREG command reads the contents of one or more device configuration registers. The Register Read command is a two-byte command followed by the register data output. The first byte contains the command and register address. The second command byte specifies the number of registers to read – 1.

First command byte:  $001r\ rrrr$ , where  $r\ rrrr$  is the starting register address.

Second command byte:  $000n\ nnnn$ , where  $n\ nnnn$  is the number of registers to read – 1.

The 17th SCLK rising edge of the operation clocks out the MSB of the first register, as shown in Figure 42. When the device is in read data continuous mode, an SDATAC command must be issued before the RREG command can be issued. The RREG command can be issued any time. However, because this command is a multi-byte command, there are SCLK rate restrictions depending on how the SCLKs are issued to meet the  $t_{SDECODE}$  timing. See the [Serial Clock \(SCLK\)](#) subsection of the [SPI Interface](#) section for more details. Note that CS must be low for the entire command.



**Figure 42. RREG Command Example: Read Two Registers Starting from Register 00h (ID Register)  
(BYTE 1 = 0010 0000, BYTE 2 = 0000 0001)**

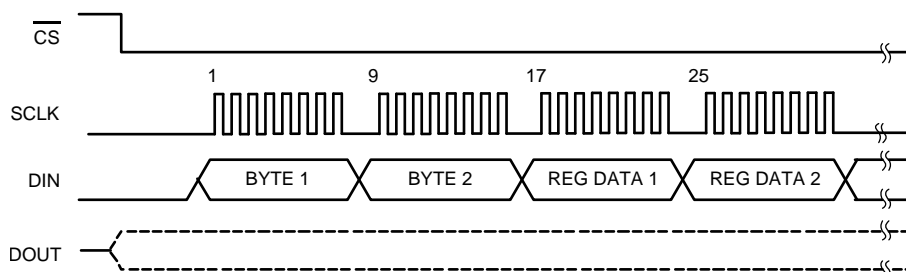
### 9.5.3.12 WREG: Write to Register

The WREG command writes data to one or more device configuration registers. The Register Write command is a two-byte command followed by the register data input. The first byte contains the command and register address. The second command byte specifies the number of registers to write – 1.

First command byte:  $010r\ rrrr$ , where  $r\ rrrr$  is the starting register address.

Second command byte:  $000n\ nnnn$ , where  $n\ nnnn$  is the number of registers to write – 1.

After the command bytes, the register data follows (in MSB-first format), as shown in Figure 43. For multiple register writes across reserved registers (0Dh–11h), these registers must be included in the register count and the default setting of the reserved register must be written. The WREG command can be issued at any time. However, because this command is a multi-byte command, there are SCLK rate restrictions depending on how the SCLKs are issued to meet the  $t_{SDECODE}$  timing. See the [Figure 1](#) for more details. CS must be low for the entire command.



**Figure 43. WREG Command Example: Write Two Registers Starting from 00h (ID Register)  
(BYTE 1 = 0100 0000, BYTE 2 = 0000 0001)**

## 9.6 Register Map

Table 10 describes the various ADS131E0x registers.

**Table 10. Register Map<sup>(1)</sup>**

ADDRESS	REGISTER	RESET VALUE (HEX)	BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
<b>DEVICE SETTINGS ( READ-ONLY REGISTERS)</b>										
00h	ID	xx	REV_ID2	REV_ID1	REV_ID0	1	0	0	NU_CH2	NU_CH1
<b>GLOBAL SETTINGS ACROSS CHANNELS</b>										
01h	CONFIG1	91	1	DAISY_IN	CLK_EN	1	0	DR[2:0]		
02h	CONFIG2	E0	1	1	1	INT_TEST	0	TEST_AMP0	TEST_FREQ[1:0]	
03h	CONFIG3	40	PDB_REFBUF	1	VREF_4V	0	OPAMP_REF	PDB_OPAMP	0	0
04h	FAULT	00	COMP_TH[2:0]			0	0	0	0	0
<b>CHANNEL-SPECIFIC SETTINGS</b>										
05h	CH1SET	10	PD1	GAIN1[2:0]			0	MUX1[2:0]		
06h	CH2SET	10	PD2	GAIN2[2:0]			0	MUX2[2:0]		
07h	CH3SET	10	PD3	GAIN3[2:0]			0	MUX3[2:0]		
08h	CH4SET	10	PD4	GAIN4[2:0]			0	MUX4[2:0]		
09h	CH5SET	10	PD5	GAIN5[2:0]			0	MUX5[2:0]		
0Ah	CH6SET	10	PD6	GAIN6[2:0]			0	MUX6[2:0]		
0Bh	CH7SET	10	PD7	GAIN7[2:0]			0	MUX7[2:0]		
0Ch	CH8SET	10	PD8	GAIN8[2:0]			0	MUX8[2:0]		
<b>FAULT DETECT STATUS REGISTERS ( READ-ONLY REGISTERS)</b>										
12h	FAULT_STATP	00	IN8P_FAULT	IN7P_FAULT	IN6P_FAULT	IN5P_FAULT	IN4P_FAULT	IN3P_FAULT	IN2P_FAULT	IN1P_FAULT
13h	FAULT_STATN	00	IN8N_FAULT	IN7N_FAULT	IN6N_FAULT	IN5N_FAULT	IN4N_FAULT	IN3N_FAULT	IN2N_FAULT	IN1N_FAULT
<b>GPIO SETTINGS</b>										
14h	GPIO	0F	GPIO4	GPIO3	GPIO2	GPIO1	GPIOC4	GPIOC3	GPIOC2	GPIOC1

(1) When using multiple register write commands, registers 0Dh, 0Eh, 0Fh, 10h, and 11h must be written to 00h.

## 9.6.1 Register Descriptions

### 9.6.1.1 ID: ID Control Register (Factory-Programmed, Read-Only) (address = 00h) [reset = xxh]

This register is programmed during device manufacture to indicate device characteristics.

**Figure 44. ID: ID Control Register**

7	6	5	4	3	2	1	0
REV_ID2	REV_ID1	REV_ID0	1	0	0	NU_CH2	NU_CH1
R-1h	R-1h	R-0h	R-1h	R-0h	R-0h	R-xh	R-xh

LEGEND: R = Read only; -n = value after reset

**Table 11. ID: ID Control Register Field Descriptions**

Bit	Field	Type	Reset	Description
7:5	REV_ID[2:0]	R	6h	<b>Device family identification.</b> This bit indicates the device family. 110 : ADS131E0x 000, 001, 010, 011, 100, 101, 111 : Reserved
4	Reserved	R	1h	<b>Reserved.</b> Always reads 1.
3:2	Reserved	R	0h	<b>Reserved.</b> Always reads 0.
1:0	NU_CH[2:0]	R	xh	<b>Device identification bits.</b> 00 : 4-channel device 01 : 6-channel device 10 : 8-channel device 11 : Reserved



### 9.6.1.2 CONFIG1: Configuration Register 1 (address = 01h) [reset = 91h]

This register configures daisy chain, the clock setting, and each ADC channel sample rate.

**Figure 45. CONFIG1: Configuration Register 1**

7	6	5	4	3	2	1	0
1	DAISY_IN	CLK_EN	1	0	DR[2:0]		
R/W-1h	R/W-1h	R/W-0h	R/W-1h	R/W-0h	R/W-4h		

LEGEND: R/W = Read/Write; -n = value after reset

**Table 12. CONFIG1: Configuration Register 1 Field Descriptions**

Bit	Field	Type	Reset	Description
7	Reserved	R/W	1h	<b>Reserved.</b> Must be set to 1. This bit reads high.
6	DAISY_IN	R/W	0h	<b>Daisy-chain and multiple data readback mode.</b> This bit determines which mode is enabled. 0 : Daisy-chain mode 1 : Multiple data readback mode
5	CLK_EN	R/W	0h	<b>CLK connection<sup>(1)</sup>.</b> This bit determines if the internal oscillator signal is connected to the CLK pin when the CLKSEL pin = 1. 0 : Oscillator clock output disabled 1 : Oscillator clock output enabled
4	Reserved	R/W	1h	<b>Reserved.</b> Must be set to 1. This bit reads high.
3	Reserved	R/W	0h	<b>Reserved.</b> Must be set to 0. This bit reads low.
2:0	DR[2:0]	R/W	1h	<b>Output data rate.</b> These bits determine the output data rate and resolution; see <a href="#">Table 13</a> for details.

(1) Additional power is consumed when driving external devices.

**Table 13. Data Rate Settings**

DR[2:0]	RESOLUTION	DATA RATE (kSPS) <sup>(1)</sup>
000	16-bit output	64
001	16-bit output	32 (default)
010	24-bit output	16
011	24-bit output	8
100	24-bit output	4
101	24-bit output	2
110	24-bit output	1
111	Do not use	NA

(1) Where  $f_{CLK} = 2.048$  MHz. Data rates scale with master clock frequency.

**9.6.1.3 CONFIG2: Configuration Register 2 (address = 02h) [reset = E0h]**

This register configures the test signal generation; see the [Input Multiplexer](#) section for more details.

**Figure 46. CONFIG2: Configuration Register 2**

7	6	5	4	3	2	1	0
1	1	1	INT_TEST	0	TEST_AMP	TEST_FREQ[1:0]	
R/W-1h	R/W-1h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	

LEGEND: R/W = Read/Write; -n = value after reset

**Table 14. CONFIG2: Configuration Register 2 Field Descriptions**

Bit	Field	Type	Reset	Description
7:5	Reserved	R/W	7h	<b>Reserved.</b> Must be set to 1. This bit reads high.
4	INT_TEST	R/W	0h	<b>Test signal source.</b> This bit determines the source for the test signal. 0 : Test signals are driven externally 1 : Test signals are generated internally
3	Reserved	R/W	0h	<b>Reserved.</b> Must be set to 0. This bit reads low.
2	TEST_AMP	R/W	0h	<b>Test signal amplitude.</b> These bits determine the calibration signal amplitude. 0 : $1 \times -(V_{VREFP} - V_{VREFN}) / 2400$ 1 : $2 \times -(V_{VREFP} - V_{VREFN}) / 2400$
1:0	TEST_FREQ[1:0]	R/W	0h	<b>Test signal frequency.</b> These bits determine the test signal frequency. 00 : Pulsed at $f_{CLK} / 2^{21}$ 01 : Pulsed at $f_{CLK} / 2^{20}$ 10 : Not used 11 : At dc

**9.6.1.4 CONFIG3: Configuration Register 3 (address = 03h) [reset = 40]**

This register configures the reference and internal amplifier operation.

**Figure 47. CONFIG3: Configuration Register 3**

7	6	5	4	3	2	1	0
PDB_REFBUF	1	VREF_4V	0	OPAMP_REF	PDB_OPAMP	0	0
R/W-0h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R-0h

LEGEND: R/W = Read/Write; -n = value after reset

**Table 15. CONFIG3: Configuration Register 3 Field Descriptions**

Bit	Field	Type	Reset	Description
7	PDB_REFBUF	R/W	0h	<b>PDB_REFBUF: Power-down reference buffer</b> This bit determines the power-down reference buffer state. 0 : Power-down internal reference buffer 1 : Enable internal reference buffer
6	Reserved	R/W	1h	<b>Reserved.</b> Must be set to 1. This bit reads high.
5	VREF_4V	R/W	0h	<b>Internal reference voltage.</b> This bit determines the internal reference voltage, VREF. 0 : VREF is set to 2.4 V 1 : VREF is set to 4 V
4	Reserved	R/W	0h	<b>Reserved.</b> Must be set to 0. This bit reads low.
3	OPAMP_REF	R/W	0h	<b>Op amp reference.</b> This bit determines whether the op amp noninverting input connects to the OPAMPP pin or to the internally-derived supply (AVDD + AVSS) / 2. 0 : Noninverting input connected to the OPAMPP pin 1 : Noninverting input connected to (AVDD + AVSS) / 2
2	PDB_OPAMP	R/W	0h	<b>Op amp power-down.</b> This bit powers down the op amp. 0 : Power-down op amp 1 : Enable op amp
1	Reserved	R/W	0h	<b>Reserved.</b> Must be set to 0. Reads back as 0.
0	Reserved	R	0h	<b>Reserved.</b> Reads back as either 1 or 0.

**9.6.1.5 FAULT: Fault Detect Control Register (address = 04h) [reset = 00h]**

This register configures the fault detection operation.

**Figure 48. FAULT: Fault Detect Control Register**

7	6	5	4	3	2	1	0
COMP_TH[2:0]			0	0	0	0	0
R/W-0h			R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

LEGEND: R/W = Read/Write; -n = value after reset

**Table 16. FAULT: Fault Detect Control Register Field Descriptions**

Bit	Field	Type	Reset	Description
7:5	COMP_TH[2:0]	R/W	0h	<b>Fault detect comparator threshold.</b> These bits determine the fault detect comparator threshold level setting. See the <a href="#">Input Out-of-Range Detection</a> section for a detailed description. <b>Comparator high-side threshold.</b> 000 : 95% 001 : 92.5% 010 : 90% 011 : 87.5% 100 : 85% 101 : 80% 110 : 75% 111 : 70% <b>Comparator low-side threshold.</b> 000 : 5% 001 : 7.5% 010 : 10% 011 : 12.5% 100 : 15% 101 : 20% 110 : 25% 111 : 30%
4:0	Reserved	R/W	00h	<b>Reserved.</b> Must be set to 0. This bit reads low.

**9.6.1.6 CHnSET: Individual Channel Settings (address = 05h to 0Ch) [reset = 10h]**

This register configures the power mode, PGA gain, and multiplexer settings for the channels; see the [Input Multiplexer](#) section for details. CHnSET are similar to CH1SET, corresponding to the respective channels (see [Table 10](#)).

**Figure 49. CHnSET<sup>(1)</sup>: Individual Channel Settings**

7	6	5	4	3	2	1	0
PDn	GAINn[2:0]			0	MUXn[2:0]		
R/W-0h	R/W-1h			R/W-0h	R/W-0h		

LEGEND: R/W = Read/Write; -n = value after reset

(1) n = 1 to 8.

**Table 17. CHnSET: Individual Channel Settings Field Descriptions**

Bit	Field	Type	Reset	Description
7	PDn	R/W	0h	<b>Power-down (n = individual channel number).</b> This bit determines the channel power mode for the corresponding channel. 0 : Normal operation 1 : Channel power-down
6:4	GAINn[2:0]	R/W	1h	<b>PGA gain (n = individual channel number).</b> These bits determine the PGA gain setting. 000 : Do not use 001 : 1 010 : 2 011 : Do not use 100 : 4 101 : 8 110 : 12 111 : Do not use
3	Reserved	R/W	0h	<b>Reserved.</b> Must be set to 0. This bit reads low.
2:0	MUXn[2:0]	R/W	0h	<b>Channel input (n = individual channel number).</b> These bits determine the channel input selection. 000 : Normal input 001 : Input shorted to (AVDD + AVSS) / 2 (for offset or noise measurements) 010 : Do not use 011 : MVDD for supply measurement 100 : Temperature sensor 101 : Test signal 110 : Do not use 111 : Do not use

**9.6.1.7 FAULT\_STATP: Fault Detect Positive Input Status (address = 12h) [reset = 00h]**

This register stores the status of whether the positive input on each channel has a fault or not. Faults are determined by comparing the input pin to a threshold set by [Table 16](#); see the [Input Out-of-Range Detection](#) section for details.

**Figure 50. FAULT\_STATP: Fault Detect Positive Input Status**

7	6	5	4	3	2	1	0
IN8P_FAULT	IN7P_FAULT	IN6P_FAULT	IN5P_FAULT	IN4P_FAULT	IN3P_FAULT	IN2P_FAULT	IN1P_FAULT
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R = Read only; -n = value after reset

**Table 18. FAULT\_STATP: Fault Detect Positive Input Status Field Descriptions**

Bit	Field	Type	Reset	Description
7	IN8P_FAULT	R	0h	<b>IN8P threshold detect.</b> 0 : Channel 8 positive input pin does not exceed threshold set 1 : Channel 8 positive input pin exceeds threshold set
6	IN7P_FAULT	R	0h	<b>IN7P threshold detect.</b> 0 : Channel 7 positive input pin does not exceed threshold set 1 : Channel 7 positive input pin exceeds threshold set
5	IN6P_FAULT	R	0h	<b>IN6P threshold detect.</b> 0 : Channel 6 positive input pin does not exceed threshold set 1 : Channel 6 positive input pin exceeds threshold set
4	IN5P_FAULT	R	0h	<b>IN5P threshold detect.</b> 0 : Channel 5 positive input pin does not exceed threshold set 1 : Channel 5 positive input pin exceeds threshold set
3	IN4P_FAULT	R	0h	<b>IN4P threshold detect.</b> 0 : Channel 4 positive input pin does not exceed threshold set 1 : Channel 4 positive input pin exceeds threshold set
2	IN3P_FAULT	R	0h	<b>IN3P threshold detect.</b> 0 : Channel 3 positive input pin does not exceed threshold set 1 : Channel 3 positive input pin exceeds threshold set
1	IN2P_FAULT	R	0h	<b>IN2P threshold detect.</b> 0 : Channel 2 positive input pin does not exceed threshold set 1 : Channel 2 positive input pin exceeds threshold set
0	IN1P_FAULT	R	0h	<b>IN1P threshold detect.</b> 0 : Channel 1 positive input pin does not exceed threshold set 1 : Channel 1 positive input pin exceeds threshold set

**9.6.1.8 FAULT\_STATN: Fault Detect Negative Input Status (address = 13h) [reset = 00h]**

This register stores the status of whether the negative input on each channel has a fault or not. Faults are determined by comparing the input pin to a threshold set by [Table 16](#); see the [Input Out-of-Range Detection](#) section for details.

**Figure 51. FAULT\_STATN: Fault Detect Negative Input Status**

7	6	5	4	3	2	1	0
IN8N_FAULT	IN7N_FAULT	IN6N_FAULT	IN5N_FAULT	IN4N_FAULT	IN3N_FAULT	IN2N_FAULT	IN1N_FAULT
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R = Read only; -n = value after reset

**Table 19. FAULT\_STATN: Fault Detect Negative Input Status Field Descriptions**

Bit	Field	Type	Reset	Description
7	IN8N_FAULT	R	0h	<b>IN8N threshold detect.</b> 0 : Channel 8 negative input pin does not exceed threshold set 1 : Channel 8 negative input pin exceeds threshold set
6	IN7N_FAULT	R	0h	<b>IN7N threshold detect.</b> 0 : Channel 7 negative input pin does not exceed threshold set 1 : Channel 7 negative input pin exceeds threshold set
5	IN6N_FAULT	R	0h	<b>IN6N threshold detect.</b> 0 : Channel 6 negative input pin does not exceed threshold set 1 : Channel 6 negative input pin exceeds threshold set
4	IN5N_FAULT	R	0h	<b>IN5N threshold detect.</b> 0 : Channel 5 negative input pin does not exceed threshold set 1 : Channel 5 negative input pin exceeds threshold set
3	IN4N_FAULT	R	0h	<b>IN4N threshold detect.</b> 0 : Channel 4 negative input pin does not exceed threshold set 1 : Channel 4 negative input pin exceeds threshold set
2	IN3N_FAULT	R	0h	<b>IN3N threshold detect.</b> 0 : Channel 3 negative input pin does not exceed threshold set 1 : Channel 3 negative input pin exceeds threshold set
1	IN2N_FAULT	R	0h	<b>IN2N threshold detect.</b> 0 : Channel 2 negative input pin does not exceed threshold set 1 : Channel 2 negative input pin exceeds threshold set
0	IN1N_FAULT	R	0h	<b>IN1N threshold detect.</b> 0 : Channel 1 negative input pin does not exceed threshold set 1 : Channel 1 negative input pin exceeds threshold set

**9.6.1.9 GPIO: General-Purpose IO Register (address = 14h) [reset = 0Fh]**

This register controls the format and state of the four GPIO pins.

**Figure 52. GPIO: General-Purpose IO Register**

7	6	5	4	3	2	1	0
GPIOD[4:1]				GPIOC[4:1]			
R/W-0h				R/W-Fh			

LEGEND: R/W = Read/Write; -n = value after reset

**Table 20. GPIO: General-Purpose IO Register Field Descriptions**

Bit	Field	Type	Reset	Description
7:4	GPIOD[4:1]	R/W	0h	<b>GPIO data.</b> These bits are used to read and write data to the GPIO ports. When reading the register, the data returned correspond to the state of the GPIO external pins, whether they are programmed as inputs or outputs. As outputs, a write to the GPIOD sets the output value. As inputs, a write to the GPIOD has no effect.
3:0	GPIOC[4:1]	R/W	Fh	<b>GPIO control (corresponding to GPIOD).</b> These bits determine if the corresponding GPIOD pin is an input or output. 0 : Output 1 : Input



## 10 Application and Implementation

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### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

---

### 10.1 Application Information

#### 10.1.1 Unused Inputs and Outputs

Power down unused analog inputs and connect them directly to AVDD.

Power down the Bias amplifier if unused and float OPAMPOUT and OPAMPN. Tie OPAMPP directly to AVSS or leave floating if unused.

Tie TESTN and TESTP to AVDD through individual 10-k $\Omega$  resistors or leave them floating if unused and the internal test signal is not used. If the internal test signal is used, leave TESTP and TESTN floating. If an external test signal is used, connect to external test circuitry.

Do not float unused digital inputs because excessive power-supply leakage current might result. Set the two-state mode setting pins high to DVDD or low to DGND through  $\geq 10$ -k $\Omega$  resistors.

Pull  $\overline{\text{DRDY}}$  to supply using weak pull-up resistor if unused.

If not daisy-chaining devices, tie DAISYIN directly to DGND.

#### 10.1.2 Setting the Device Up for Basic Data Capture

This section outlines the procedure to configure the device in a basic state and capture data. This procedure is intended to put the device in a data sheet condition to check if the device is working properly in the user system. It is recommended that this procedure be followed initially to get familiar with the device settings. When this procedure is verified, the device can be configured as needed. For details on the timings for commands refer to the appropriate sections in the data sheet. The flow chart of [Figure 53](#) details the initial ADS131E0x configuration and setup.

Application Information (continued)

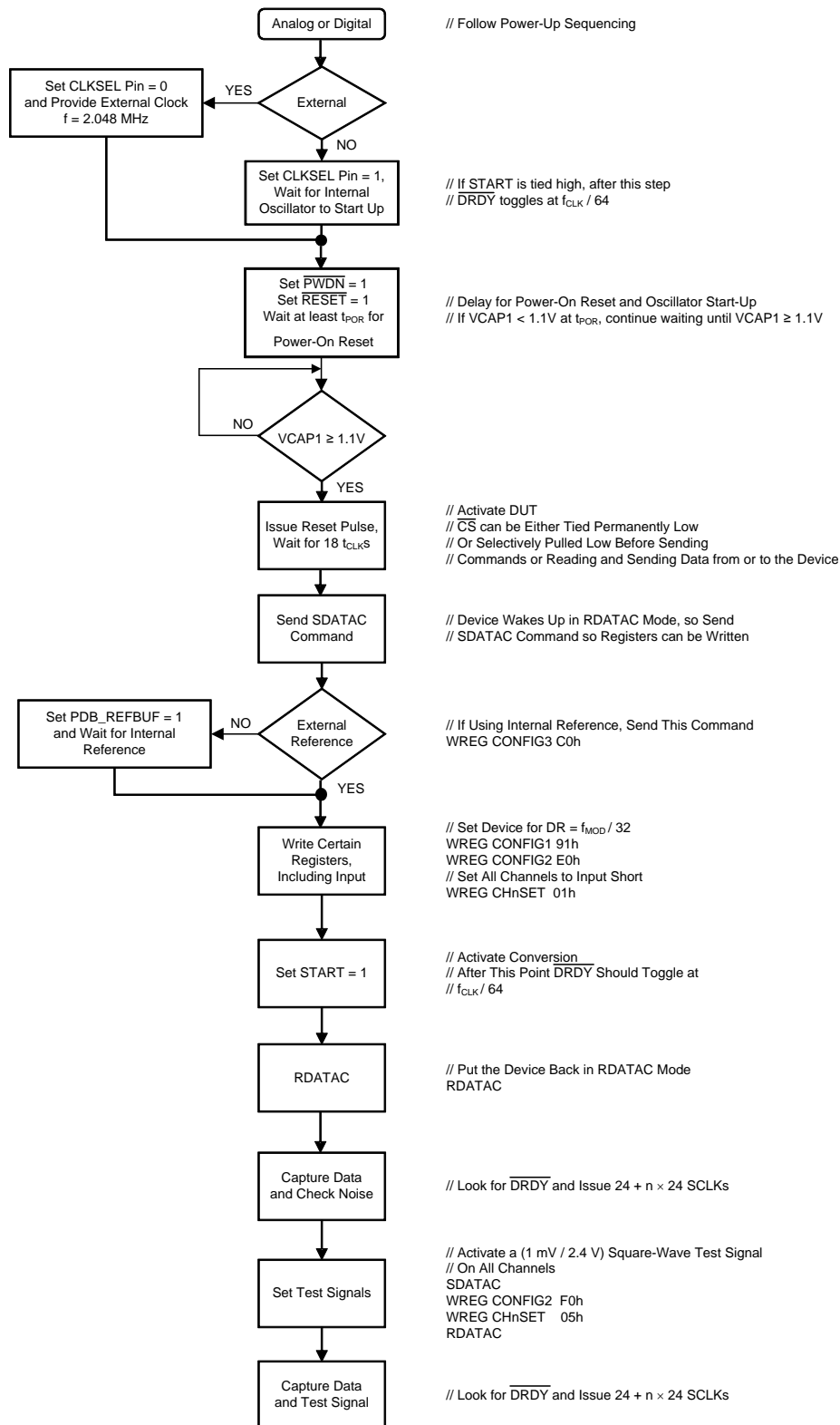


Figure 53. Initial Flow at Power Up

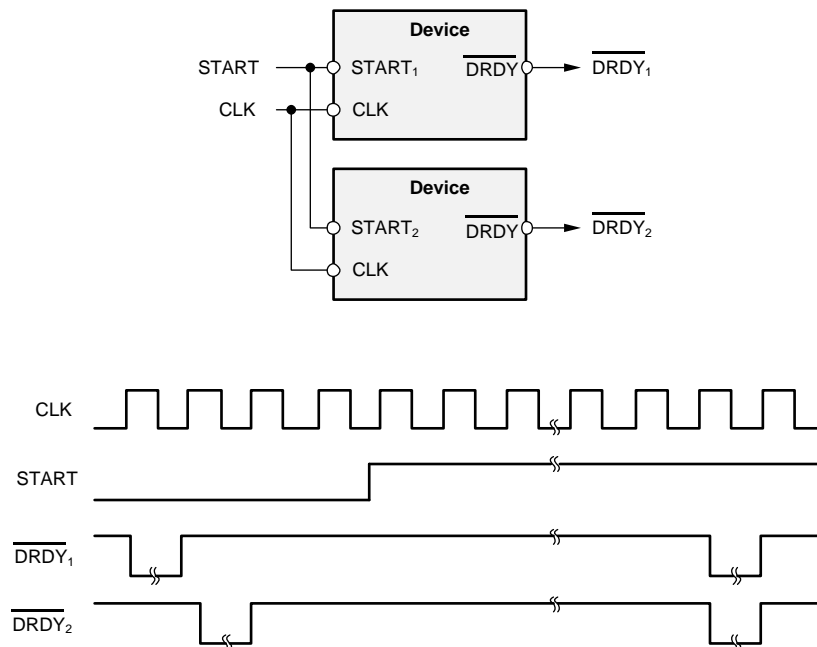
## Application Information (continued)

### 10.1.3 Multiple Device Configuration

The ADS131E0x provides configuration flexibility when multiple devices are used in a system. The serial interface typically needs four signals: DIN, DOUT, SCLK, and  $\overline{CS}$ . With one additional chip select signal per device, multiple devices can be operated on the same SPI bus. The number of signals needed to interface to  $N$  devices is  $3 + N$ .

#### 10.1.3.1 Synchronizing Multiple Devices

When using multiple devices, the devices can be synchronized using the START signal. The delay time from the rising edge of the START signal to the falling edge of the  $\overline{DRDY}$  signal is fixed for a given data rate (see the [Start](#) section for more details on the settling times). [Figure 54](#) shows the behavior of two devices when synchronized with the START signal.



**Figure 54. Synchronizing Multiple Converters**

To use the internal oscillator in a daisy-chain configuration, one device must be set as the master for the clock source with the internal oscillator enabled (CLKSEL pin = 1) and the internal oscillator clock must be brought out of the device by setting the  $\overline{CLK\_EN}$  register bit to 1. The master device clock is used as the external clock source for the other devices.

There are two ways to connect multiple devices with an optimal number of interface pins: standard configuration and daisy-chain configuration.

#### 10.1.3.2 Standard Configuration

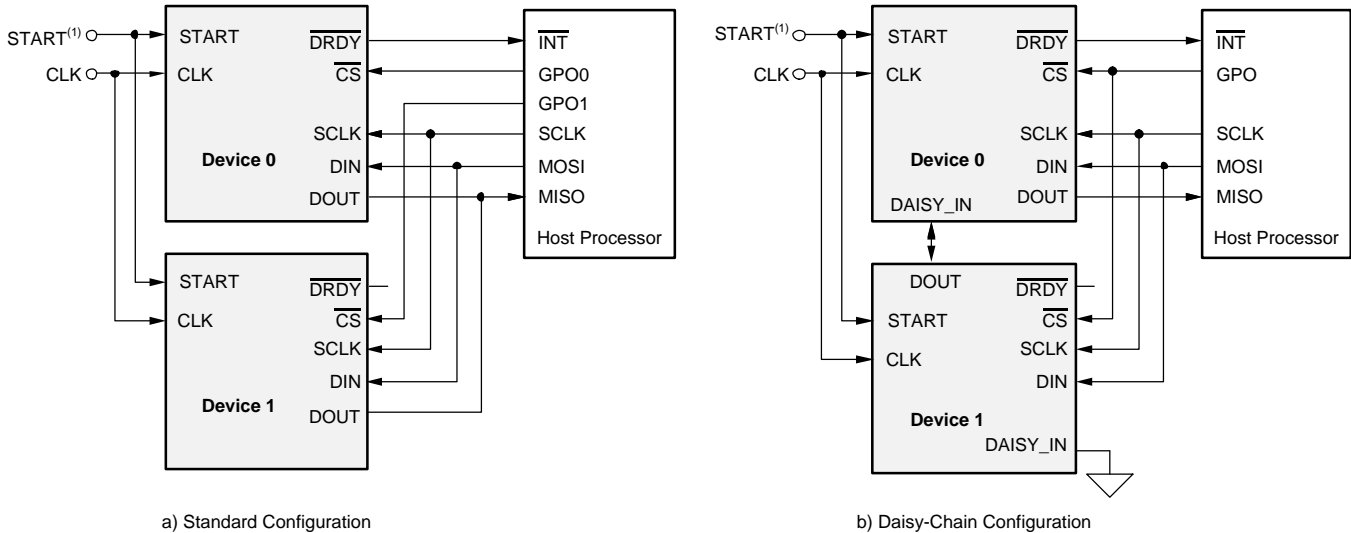
[Figure 55a](#) shows a configuration with two ADS131E0x devices cascaded. Together, the devices create a system with up to 16 channels. DOUT, SCLK, and DIN are shared. Each device has its own chip select. When a device is not selected by the corresponding  $\overline{CS}$  being driven to logic 1, the DOUT pin of this device is high-impedance. This structure allows the other device to take control of the DOUT bus. This configuration method is suitable for the majority of applications where extra I/O pins are available.

## Application Information (continued)

### 10.1.3.3 Daisy-Chain Configuration

Daisy-chain mode is enabled by setting the DAISY\_IN bit in the CONFIG1 register. Figure 55b shows the daisy-chain configuration. In this mode SCLK, DIN, and  $\overline{CS}$  are shared across multiple devices. The DOUT pin of device 1 is connected to the DAISY\_IN pin of device 0, thereby creating a daisy-chain for the data. Connect the DAISY\_IN pin of device 1 to DGND if not used. The daisy-chain timing requirements for the SPI interface are illustrated in Figure 2. Data from the ADS131E0x device 0 appear first on DOUT, followed by a *don't care* bit, and then the status and data words from the ADS131E0x device 1.

The internal oscillator output cannot be enabled because all devices in the chain operate by sharing the same DIN pin, thus an external clock must be used.



(1) To reduce pin count, set the START pin low and use the START command to synchronize and start conversions.

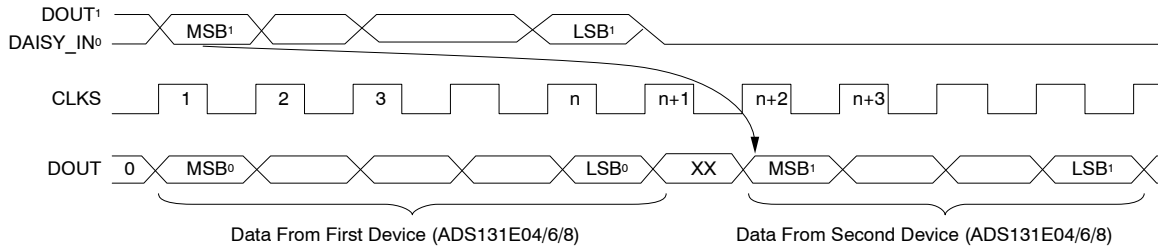
**Figure 55. Multiple Device Configurations**

There are several items to be aware of when using daisy-chain mode:

1. One extra SCLK must be issued between each data set (see Figure 56)
2. All devices are configured to the same register values because the  $\overline{CS}$  signal is shared
3. Device register readback is only valid for device 0 in the daisy-chain. Only ADC conversion data can be read back from device 1 through device  $N$ , where  $N$  is the last device in the chain.

## Application Information (continued)

The more devices in the chain, the more challenging adhering to setup and hold times becomes. A star-pattern connection of SCLK to all devices, minimizing the trace length of DOUT, and other printed circuit board (PCB) layout techniques helps to mitigate this challenge with signal delays. Placing delay circuits (such as buffers) between DOUT and DAISY\_IN are options to help reduce signal delays. One other option is to insert a *D* flip-flop between DOUT and DAISY\_IN clocked on an inverted SCLK. [Figure 56](#) shows a timing diagram for daisy-chain mode.



NOTE:  $n = (\text{number of channels}) \times (\text{resolution}) + 24$  bits. The number of channels is 8. Resolution is 16 bits or 24 bits.

**Figure 56. Daisy-Chain Data Word**

The maximum number of devices that can be daisy-chained depends on the data rate that the devices are operated at. The maximum number of devices can be calculated with [Equation 10](#).

$$N_{\text{DEVICES}} = \frac{f_{\text{SCLK}}}{f_{\text{DR}} (N_{\text{BITS}})(N_{\text{CHANNELS}}) + 24}$$

where:

- $N_{\text{BITS}}$  = device resolution (depends on DR[2:0] setting)
  - $N_{\text{CHANNELS}}$  = number of channels powered up in the device
- (10)

For example, when the ADS131E0x is operated in 24-bit, 8-kSPS data rate with  $f_{\text{SCLK}} = 10$  MHz, up to six devices can be daisy-chained together.

### 10.1.4 Power Monitoring Specific Applications

All channels of the ADS131E0x are exactly identical, yet independently configurable, thus giving the user the flexibility of selecting any channel for voltage or current monitoring. An overview of a system configured to monitor voltage and current is illustrated in [Figure 57](#). Also, the simultaneously sampling capability of the device allows the user to monitor both the current and the voltage at the same time. The full-scale differential input voltage of each channel is determined by the PGA gain setting (see the [CHnSET: Individual Channel Settings](#) section) for the respective channel and  $V_{\text{REF}}$  (see the [CONFIG3: Configuration Register 3](#) section).

Application Information (continued)

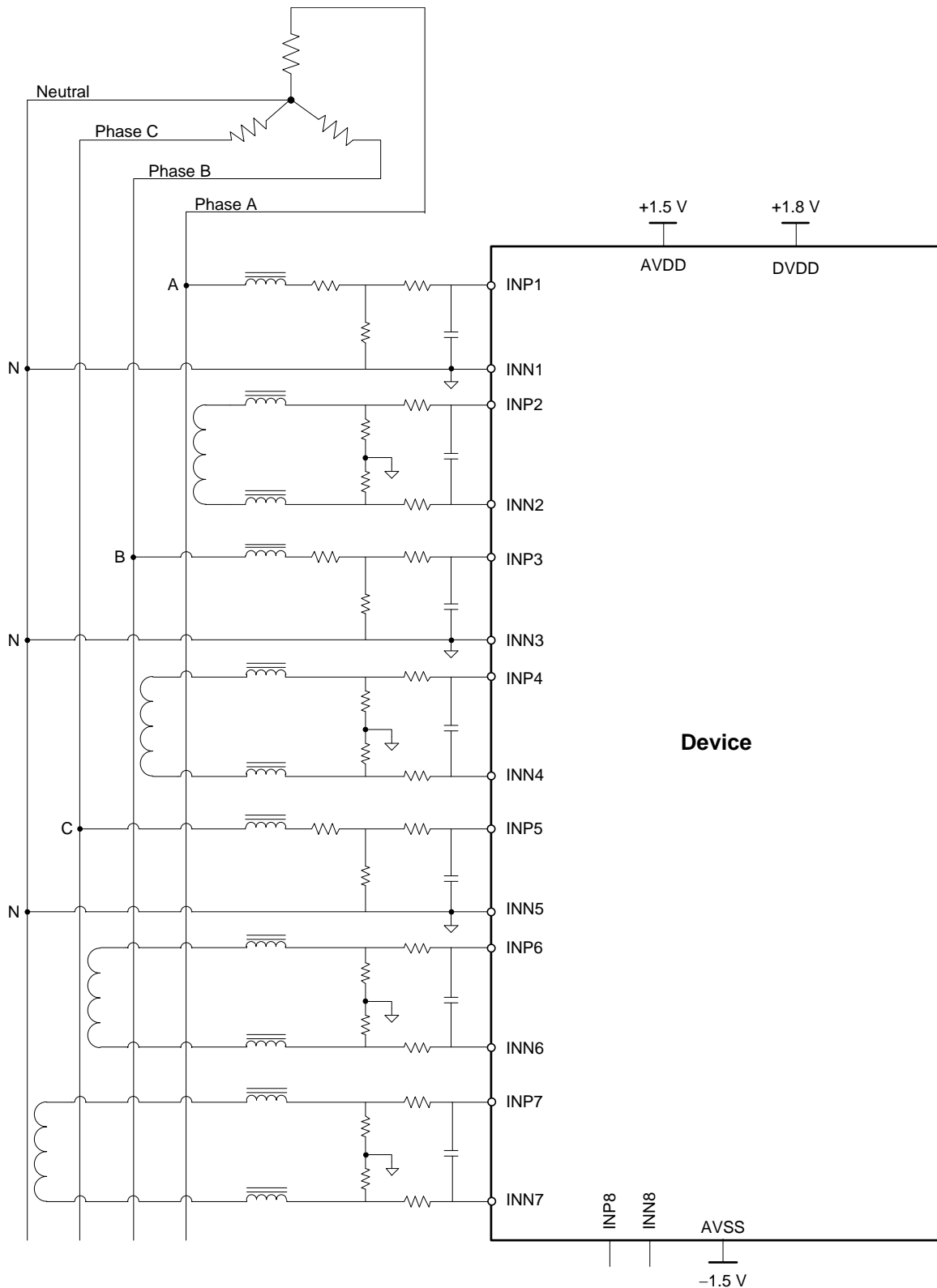


Figure 57. Overview of a Power-Monitoring System

## Application Information (continued)

### 10.1.5 Current Sensing

**Figure 58** illustrates a simplified diagram of typical configurations used for current sensing with a Rogowski coil, current transformer (CT), or an air coil that outputs a current or voltage. In the case of a current output transformer, the burden resistors (R1) are used for current-to-voltage conversion. The output of the burden resistors is connected to the ADS131E0x INxP and INxN inputs through an antialiasing RC filter for current sensing. In the case of a voltage output transformer for current sensing (such as certain types of Rogowski coils), the output terminals of the transformer are directly connected to the ADS131E0x INxP and INxN inputs through an antialiasing RC filter. The input network must be biased to mid-supply if using a unipolar-supply analog configuration ( $AVSS = 0\text{ V}$ ,  $AVDD = 2.7\text{ V}$  to  $5.5\text{ V}$ ). The common-mode bias voltage  $[(AVDD + AVSS) / 2]$  can be obtained from the ADS131E0x by either configuring the internal op amp in a unity-gain configuration using the  $R_F$  resistor and setting the OPAMP\_REF bit of the CONFIG3 register to 1, or generated externally with a resistor divider network between the positive and negative supplies.

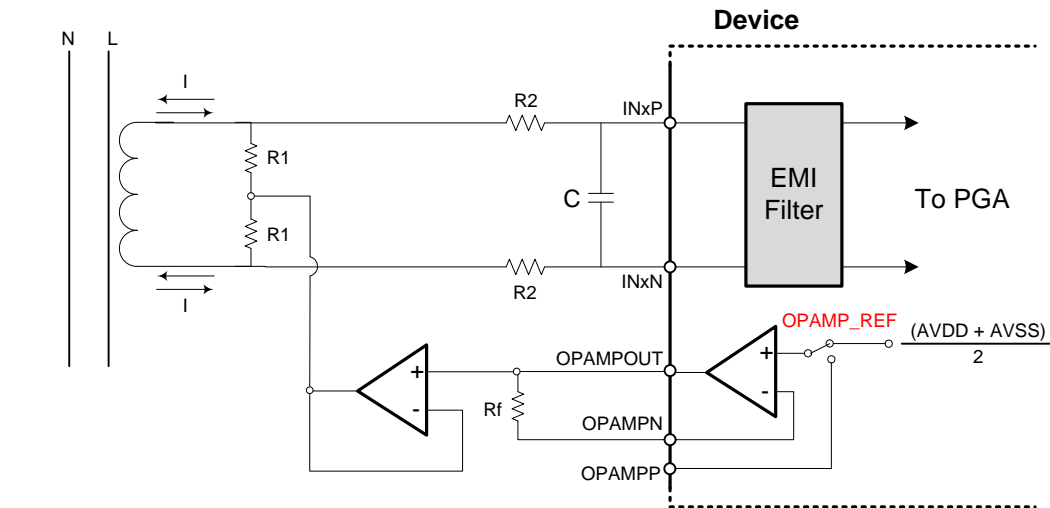
Select the value of resistor R1 for the current output transformer and turns ratio of the transformer such that the ADS131E0x full-scale differential input voltage range is not exceeded. Likewise, select the output voltage for the voltage output transformer to not exceed the full-scale differential input voltage range. In addition, the selection of the resistors (R1 and R2) and turns ratio must not saturate the transformer over the full operating dynamic range. **Figure 58a** illustrates differential input current sensing and **Figure 58b** illustrates single-ended input voltage sensing. Use separate external op amps to source and sink current because the internal op amp has very limited current sink and source capability. Additionally, separate op amps for each channel help isolate individual phases from one another to limit crosstalk.

### 10.1.6 Voltage Sensing

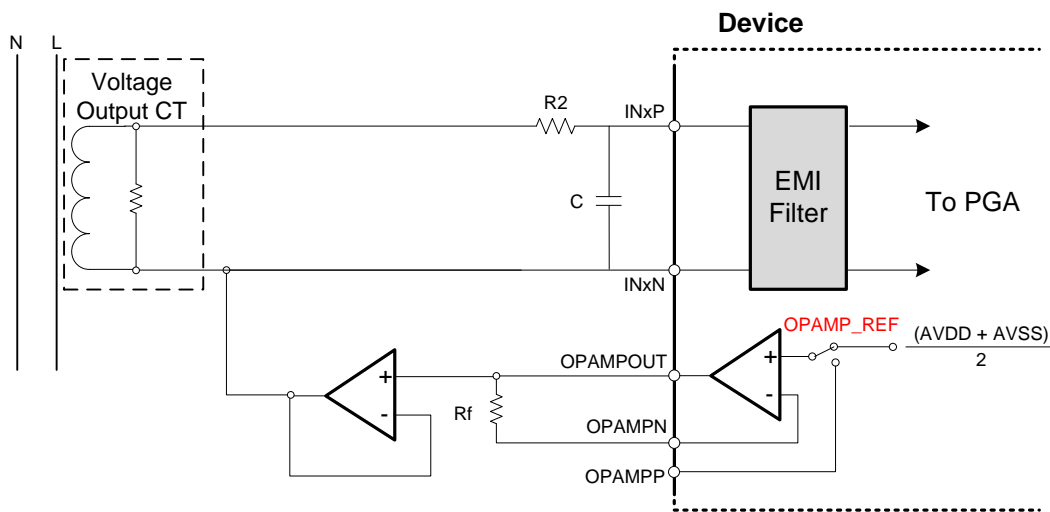
**Figure 59** illustrates a simplified diagram of commonly-used differential and single-ended methods of voltage sensing. A resistor divider network is used to step down the line voltage to within the acceptable ADS131E0x input range and then connect to the inputs (INxP and INxN) through an antialiasing RC filter formed by resistor R3 and capacitor C. The common-mode bias voltage  $[(AVDD + AVSS) / 2]$  can be obtained from the ADS131E0x by either configuring the internal op amp in a unity-gain configuration using the  $R_F$  resistor and setting the OPAMP\_REF bit of the CONFIG3 register, or generated externally by using a resistor divider network between the positive and negative supplies.

In either of the cases illustrated in **Figure 59** (**Figure 59a** for a differential input and **Figure 59b** for a single-ended input), the line voltage is divided down by a factor of  $[R2 / (R1 + R2)]$ . Values of R1 and R2 must be carefully chosen so that the voltage across the ADS131E0x inputs (INxP and INxN) does not exceed the range of the ADS131E0x over the full operating dynamic range. Use separate external op amps to source and sink current because the internal op amp has very limited current sink and source capability. Additionally, separate op amps for each channel help isolate individual phases from one another to limit crosstalk.

Application Information (continued)



(a) Current Output CT with Differential Input

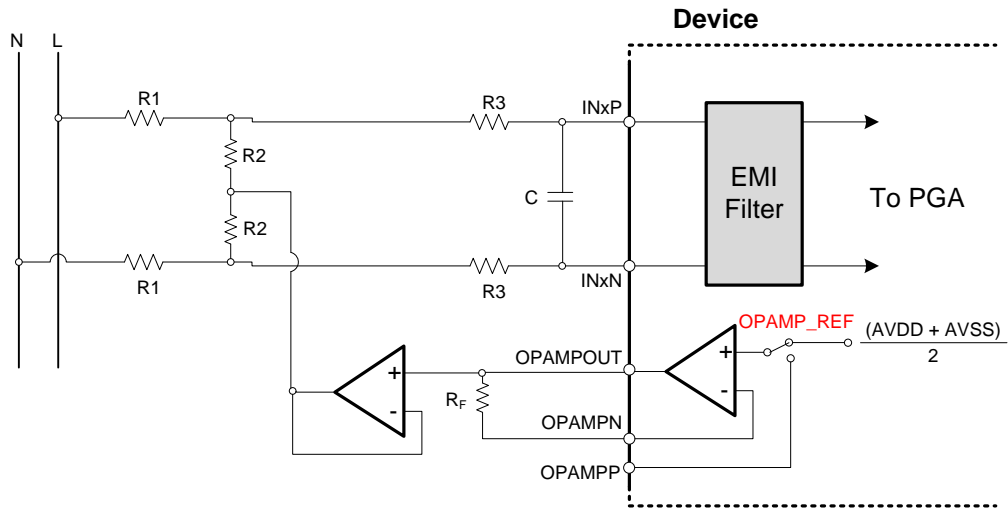


(b) Voltage Output CT with Single-Ended Input

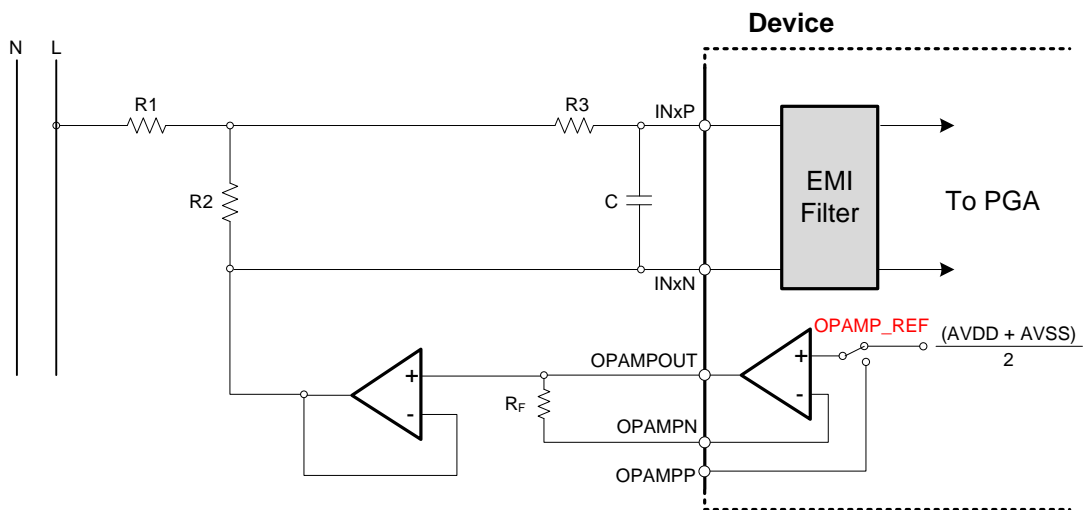
Figure 58. Simplified Current-Sensing Connections



Application Information (continued)



(a) Voltage Sensing with Differential Input



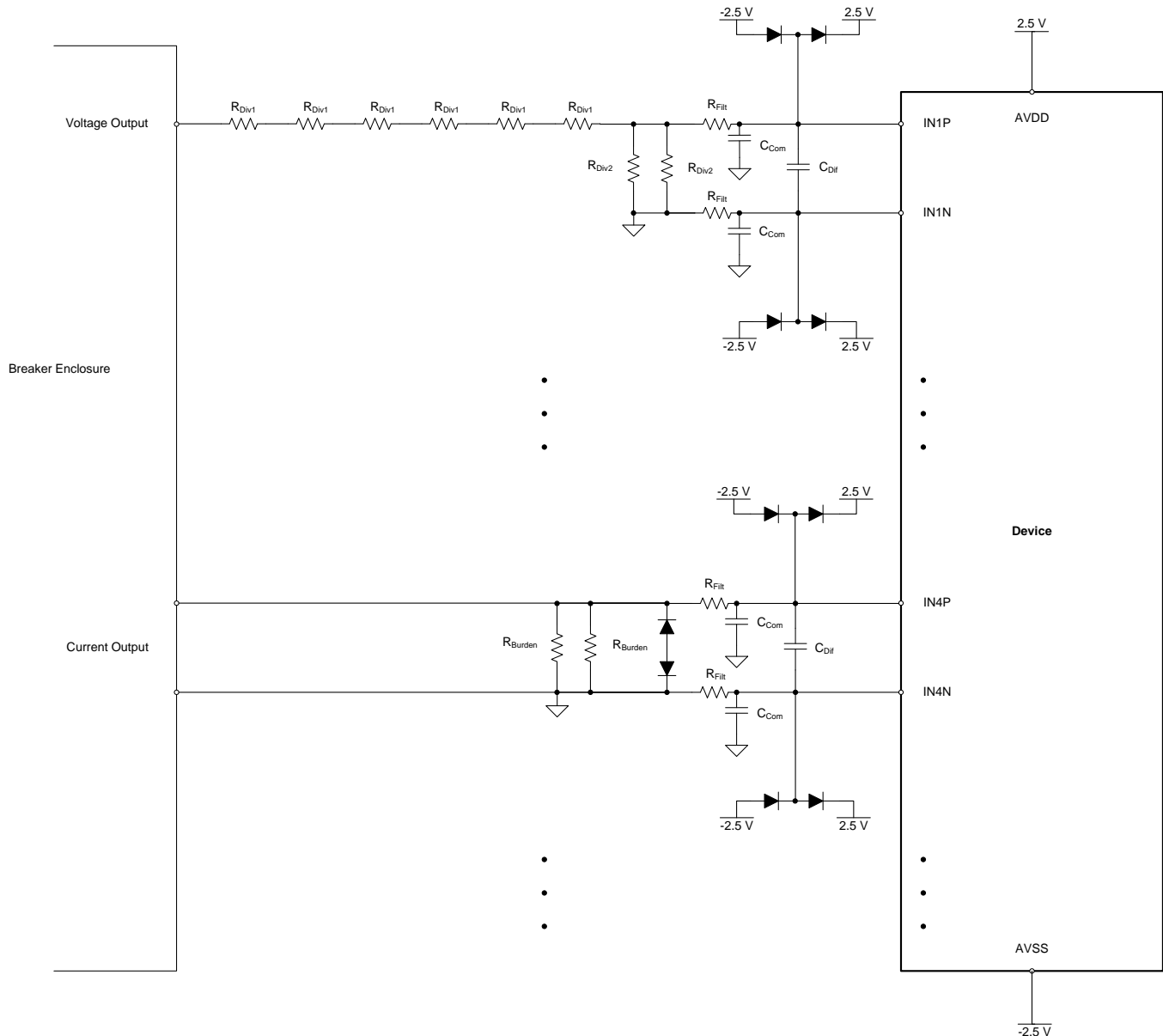
(b) Voltage Sensing with Single-Ended Input

Figure 59. Simplified Voltage-Sensing Connections

## 10.2 Typical Application

Figure 60 shows the ADS131E0x being used as part of an electronic trip unit (ETU) in a circuit breaker or protection relay. Delta-sigma ( $\Delta\Sigma$ ), analog-to-digital converters (ADCs), such as the ADS131E0x, are ideal for this application because these devices provide a wide dynamic range.

The system measures voltages and currents output from a breaker enclosure. In this example, the first three inputs measure line voltage and the remaining five inputs measure line current from the secondary winding of a current transformer (CT). A voltage divider steps down the voltage from the output of the breaker. Several resistors are used to break up power consumption and are used as a form of fault protection against any potential resistor short-circuit. After the voltage step down, RC filters are used for antialiasing and diodes protect the inputs from overrange.



**Figure 60. ETU Block Diagram: High-Resolution and Fast Power-Up Analog Front-End for Air Circuit Breaker or Molded Case Circuit Breaker and Protection Relay**

### 10.2.1 Design Requirements

Table 21 summarizes the design requirements for the circuit breaker front-end application.

**Table 21. ETU Circuit Breaker Design Requirements**

DESIGN PARAMETER	VALUE
Number of voltage inputs	3
Voltage input range	10 V to 750 V
Number of current inputs	5
Current input range	50 mA to 25 A
Dynamic range with fixed gain	> 500:1
Accuracy	±1%

### 10.2.2 Detailed Design Procedure

The line voltage is stepped down to a voltage range within the measurable range of the ADC. The reference voltage determines the range in which the ADC can measure signals. The ADS131E0x has two integrated low-drift reference voltage options: 2.4 V and 4 V.

Equation 11 describes the transfer function for the voltage divider at the input in Figure 60. Using multiple series resistors,  $R_{DIV1}$ , and multiple parallel resistors,  $R_{DIV2}$ , allows for power and heat to be dissipated among several circuit elements and serves as protection against a potential short-circuit across a single resistor. The number of resistors trade off with nominal accuracy because each additional element introduces an additional source of tolerance.

$$V_{IN} = V_{Phase} \times \left( \frac{0.5 \times R_{Div2}}{6 \times R_{Div1} + 0.5 \times R_{Div2}} \right) \quad (11)$$

The step-down resistor,  $R_{DIV2}$ , dominates the measurement error produced by the resistor network. Using input PGAs on the ADS131E0x helps to mitigate this error source by allowing  $R_{DIV2}$  to be made smaller and then amplifying the signal to near full-scale using the ADS131E0x PGA.

For this design,  $R_{DIV1}$  is set to 200 k $\Omega$  and  $R_{DIV2}$  is set to 2.4 k $\Omega$  to provide proper signal attenuation at a sufficient power level across each resistor. The input saturates at values greater than  $\pm 750$  V when using the ADS131E0x internal 2.4-V reference and a PGA gain of 2.

The ADS131E0x measures the line current by creating a voltage across the burden resistance ( $R_{Burden}$  in Figure 60) in parallel with the secondary winding of a CT. As with the voltage measurement front-end, multiple resistors ( $R_{DIV1}$ ) that are used to step down a voltage share the duty of dissipating power. In this design,  $R_{BURDEN}$  is set to 33  $\Omega$ . Used with a 1:500 turns ratio CT, the ADC input saturates with a line current over 25 A when the ADC is configured using the internal 2.4-V reference and a PGA gain of 2.

Diodes protect the ADS131E0x inputs from overvoltage and current. Diodes on each input shunt to either supply if the input voltage exceeds the safe range for the device. On current inputs, a diode shunts the inputs if current on the secondary winding of the CT threatens to damage the device.

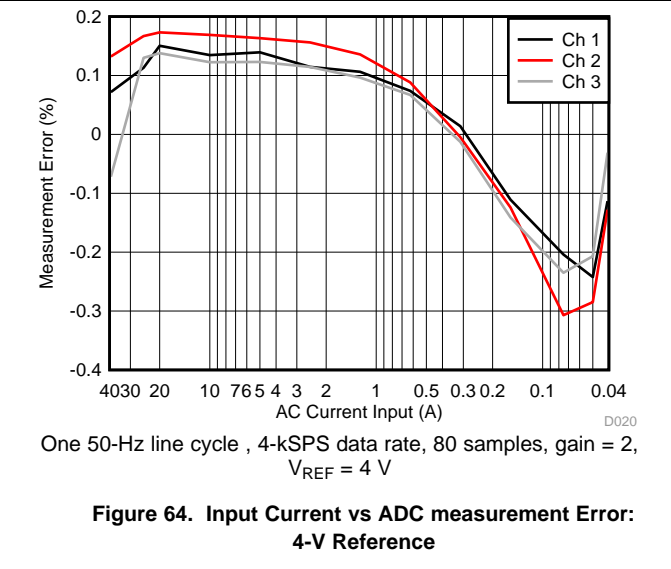
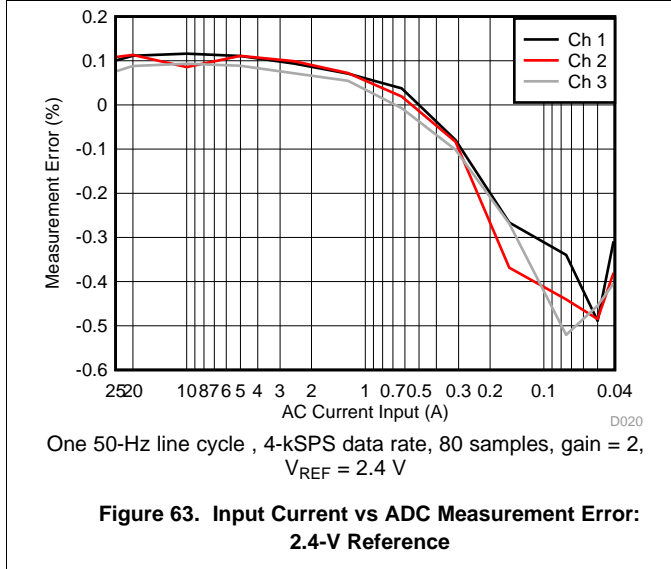
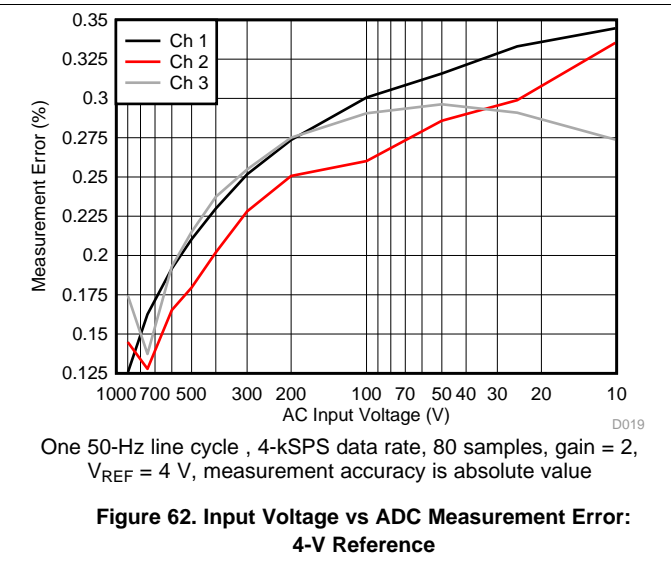
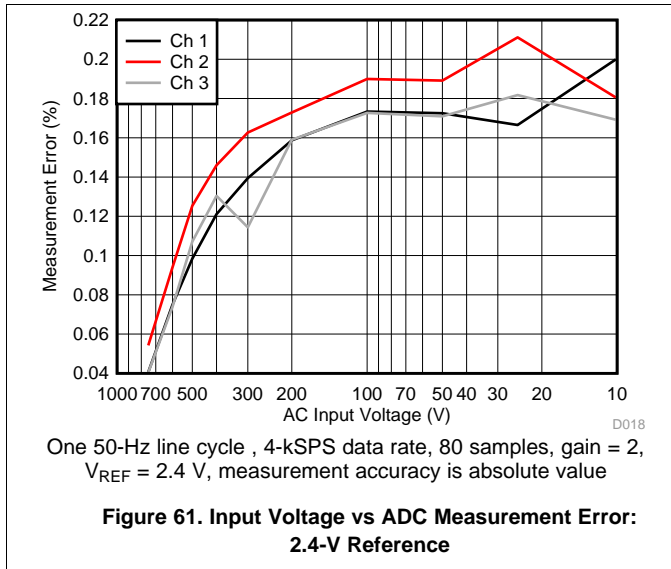
The combination of  $R_{Filt}$ ,  $C_{Com}$ , and  $C_{Dif}$  form the antialiasing filters for each of the inputs. The differential capacitor  $C_{Dif}$  improves the common-mode rejection of the system by sharing its tolerance between the positive and negative input. The antialiasing filter requirement is not strict because the nature of a  $\Delta\Sigma$  converter (with oversampling and digital filter) attenuates a significant proportion of out-of-band noise. In addition, the input PGAs have intentionally low bandwidth to provide additional antialiasing. The component values used in this design are  $R_{Filt} = 1$  k $\Omega$ ,  $C_{Com} = 47$  pF, and  $C_{Dif} = 0.015$   $\mu$ F. This first-order filter produces a relatively flat frequency response beyond 2 kHz, capable of measuring greater than 30 harmonics at a 50-Hz or 60-Hz fundamental frequency. The 3-dB cutoff frequency of the filter is 5.3 kHz for each input channel.


Each analog system block introduces errors from input to output. Protection CTs in the 5P accuracy class can introduce as much as  $\pm 1\%$  current error from input to output. CTs in the 10P accuracy class can introduce as much as  $\pm 3\%$  error. The burden resistor also introduces errors in the form of resistor tolerance and temperature drift. For the voltage input, error comes from the divider network in the form of resistor tolerance and temperature drift. Finally, the converter introduces errors in the form of offset error, gain error, and reference error. All of these specifications can drift over temperature.

### 10.2.3 Application Curves

Accuracy is measured using a system designed in a similar way to that illustrated in Figure 60. The CT used for the current input is CT1231 (a 0.3 class, solid core, 5:2500 turns transformer). In each case, data are taken for three channels over one cycle of the measured waveform and the RMS input-referred signal is compared to the output to calculate the error. The equation used to derive the measurement error is shown in Equation 12. Data are taken using both the 2.4-V and 4-V internal reference voltages. In all cases, measured accuracy is within ±1%.

$$\text{Measurement Accuracy}(\%) = \left( \frac{\text{Measured} - \text{Actual}}{\text{Actual}} \right) \times 100 \tag{12}$$





For a step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, see [High Resolution, Fast Startup Analog Front End for Air Circuit Breaker Design Guide \(TIDUB80\)](#).

## 11 Power Supply Recommendations

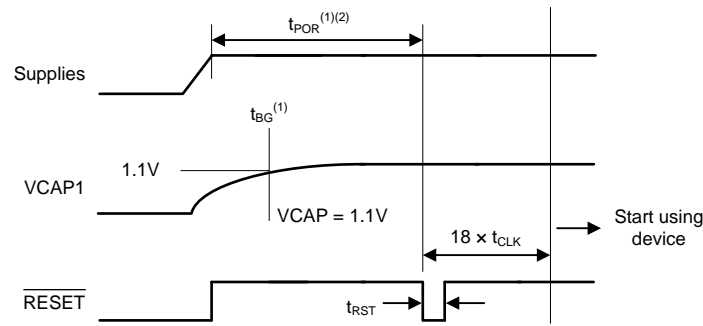
### 11.1 Power-Up Timing

Before device power up, all digital and analog inputs must be low. At the time of power up, keep all of these signals low until the power supplies have stabilized, as shown in Figure 65.

Allow time for the supply voltages to reach their final value, and then begin supplying the master clock signal to the CLK pin. Wait for time  $t_{POR}$ , then transmit a reset pulse using either the  $\overline{RESET}$  pin or RESET command to initialize the digital portion of the chip. Issue the reset after  $t_{POR}$  or after the VCAP1 voltage is greater than 1.1 V, whichever time is longer. Note that:

- $t_{POR}$  is described in Table 22.
- The VCAP1 pin charge time is set by the RC time constant set by the capacitor value on VCAP1; see Figure 28.

After releasing RESET, the configuration registers must be programmed (see the *CONFIG1: Configuration Register 1 (address = 01h) [reset = 91h]* subsection of the *Register Map* section for details) to the desired settings. The power-up sequence timing is shown in Table 22.



- (1) Timing to reset pulse is  $t_{POR}$  or after  $t_{BG}$ , whichever is longer.  
 (2) When using an external clock,  $t_{POR}$  timing does not start until CLK is present and valid.

**Figure 65. Power-Up Timing Diagram**

**Table 22. Timing Requirements for Figure 65**

		MIN	MAX	UNIT
$t_{POR}$	Wait after power up until reset	$2^{18}$		$t_{CLK}$
$t_{RST}$	Reset low duration	1		$t_{CLK}$

## 11.2 Recommended External Capacitor Values

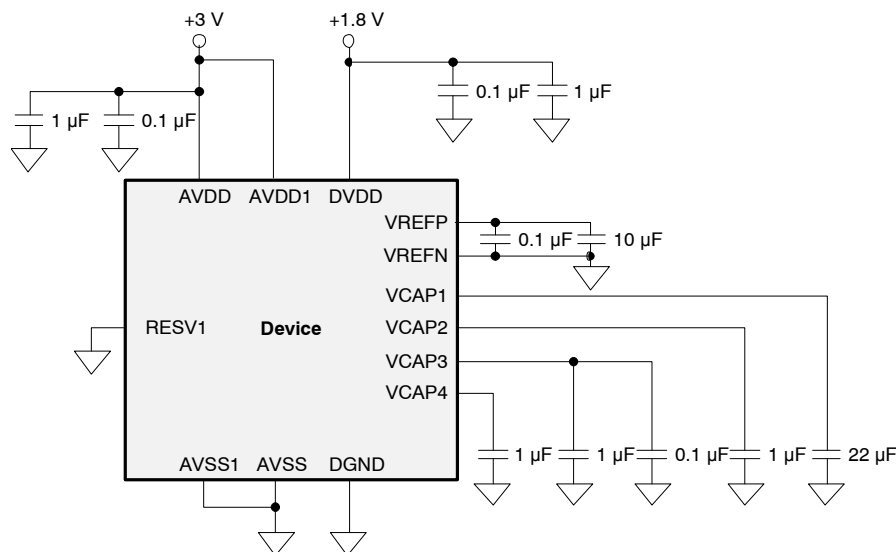
The ADS131E0x power-up time is set by the time required for the critical voltage nodes to settle to their final values. The analog supplies (AVDD and AVSS), digital supply (DVDD), and internal node voltages (VCAPx pins) must be up and stable when the data converter samples are taken to ensure performance. The combined current sourcing capability of the supplies and size of the bypass capacitors dictate the ramp rate of AVDD, AVSS, and DVDD. The VCAPx voltages are charged internally using the supply voltages. [Table 23](#) lists the internal node voltages, their function, and recommended capacitor values to optimize the power-up time.

**Table 23. Recommended External Capacitor Values**

PIN		FUNCTION	RECOMMENDED CAPACITOR VALUE
NAME	NO.		
VCAP1	28	Band-gap voltage for the ADC	22 $\mu$ F to AVSS
VCAP2	30	Modulator common-mode	1 $\mu$ F to AVSS
VCAP3	55	PGA charge pump	0.1 $\mu$ F    1 $\mu$ F to AVSS
VCAP4	26	Reference common-mode	1 $\mu$ F to AVSS
VREFP	24	Reference voltage after the internal buffer	0.1 $\mu$ F    10 $\mu$ F to AVSS
AVDD	19, 21, 22, 56, 59	Analog supply	0.1 $\mu$ F    1 $\mu$ F each to AVSS
AVDD1	54	Internal PGA charge pump analog supply	0.1 $\mu$ F    1 $\mu$ F to AVSS1
DVDD	48, 50	Digital supply	0.1 $\mu$ F    1 $\mu$ F each to DGND

## 11.3 Device Connections for Unipolar Power Supplies

[Figure 66](#) shows the ADS131E0x connected to a unipolar supply. In this example, the analog supply (AVDD) is referenced to the analog ground (AVSS) and the digital supply (DVDD) is referenced to the digital ground (DGND). The ADS131E0x supports an analog supply range of AVDD = 2.7 V to 5.25 V when operated in unipolar supply mode.

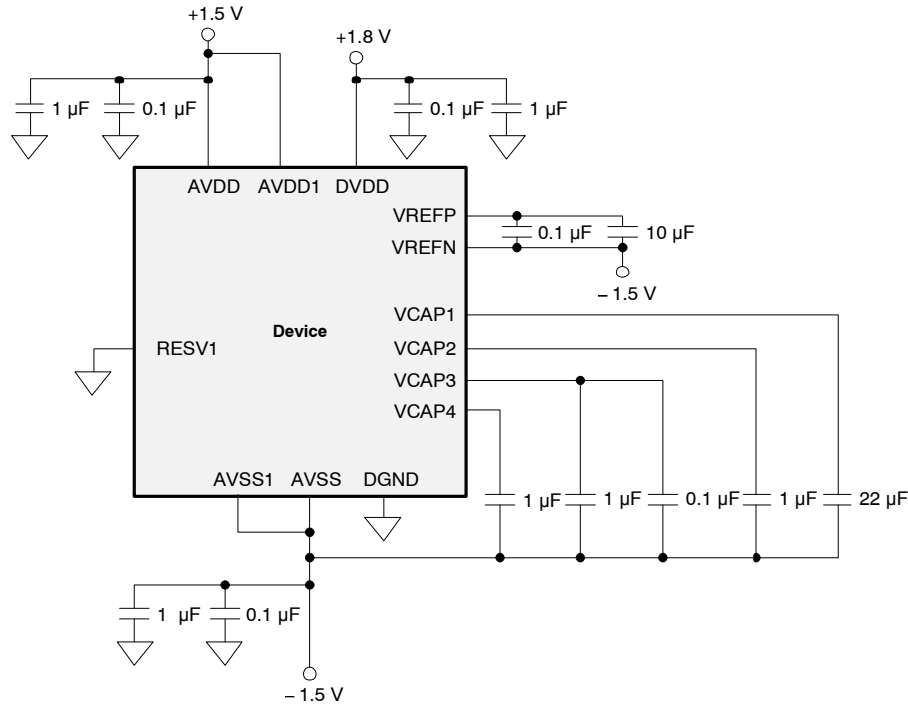


NOTE: Place the supply, reference, and VCAP1 to VCAP4 capacitors as close to the package as possible.

**Figure 66. Unipolar Power Supply Operation**

## 11.4 Device Connections for Bipolar Power Supplies

Figure 67 shows the ADS131E0x connected to a bipolar supply. In this example, the analog supply (AVDD) is referenced to the analog ground (AVSS) and the digital supply (DVDD) is referenced to the digital ground (DGND). The ADS131E0x supports an analog supply range of AVDD and AVSS = ±1.5 V to ±2.5 V when operated in bipolar supply mode.



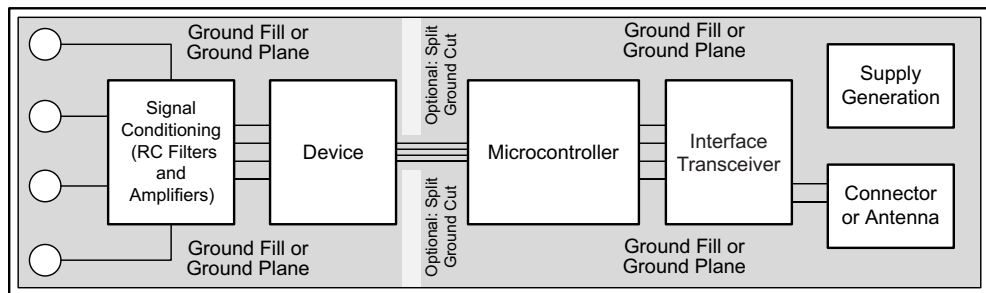
NOTE: Place the supply, reference, and VCAP1 to VCAP4 capacitors as close to the package as possible.

**Figure 67. Bipolar Power Supply Operation**

## 12 Layout

### 12.1 Layout Guidelines

TI recommends employing best design practices when laying out a printed-circuit board (PCB) for both analog and digital components. This recommendation generally means that the layout separates analog components (such as ADCs, amplifiers, references, digital-to-analog converters (DACs), and analog MUXs) from digital components (such as microcontrollers, complex programmable logic devices (CPLDs), field-programmable gate arrays (FPGAs), radio frequency (RF) transceivers, universal serial bus (USB) transceivers, and switching regulators). An example of good component placement is shown in [Figure 68](#). Although [Figure 68](#) provides a good example of component placement, the best placement for each application is unique to the geometries, components, and PCB fabrication capabilities employed. That is, there is no single layout that is perfect for every design and careful consideration must always be used when designing with any analog component.



**Figure 68. System Component Placement**

The following outlines some basic recommendations for the layout of the ADS131E0x to get the best possible performance of the ADC. A good design can be ruined with a bad circuit layout.

- Separate analog and digital signals. To start, partition the board into analog and digital sections where the layout permits. Route digital lines away from analog lines. This configuration prevents digital noise from coupling back into analog signals.
- The ground plane can be split into an analog plane (AGND) and digital plane (DGND), but is not necessary. Place digital signals over the digital plane, and analog signals over the analog plane. As a final step in the layout, the split between the analog and digital grounds must be connected together at the ADC.
- Fill void areas on signal layers with ground fill.
- Provide good ground return paths. Signal return currents flow on the path of least impedance. If the ground plane is cut or has other traces that block the current from flowing right next to the signal trace, then the current must find another path to return to the source and complete the circuit. If current is forced into a longer path, the chances that the signal radiates increases. Sensitive signals are more susceptible to EMI interference.
- Use bypass capacitors on supplies to reduce high-frequency noise. Do not place vias between bypass capacitors and the active device. Placing the bypass capacitors on the same layer as close to the active device yields the best results.
- Analog inputs with differential connections must have a capacitor placed differentially across the inputs. The differential capacitors must be of high quality. The best ceramic chip capacitors are C0G (NPO), which have stable properties and low noise characteristics.

### 12.2 Layout Example

[Figure 69](#) shows an example layout of the ADS131E0x requiring a minimum of two PCB layers. The example circuit is shown for either a unipolar analog supply connection or a bipolar analog supply connection. In this example, polygon pours are used as supply connections around the device. If a three- or four-layer PCB is used, the additional inner layers can be dedicated to route power traces. The PCB is partitioned with analog signals routed from the left, digital signals routed to the right, and power routed above and below the device.



Layout Example (continued)

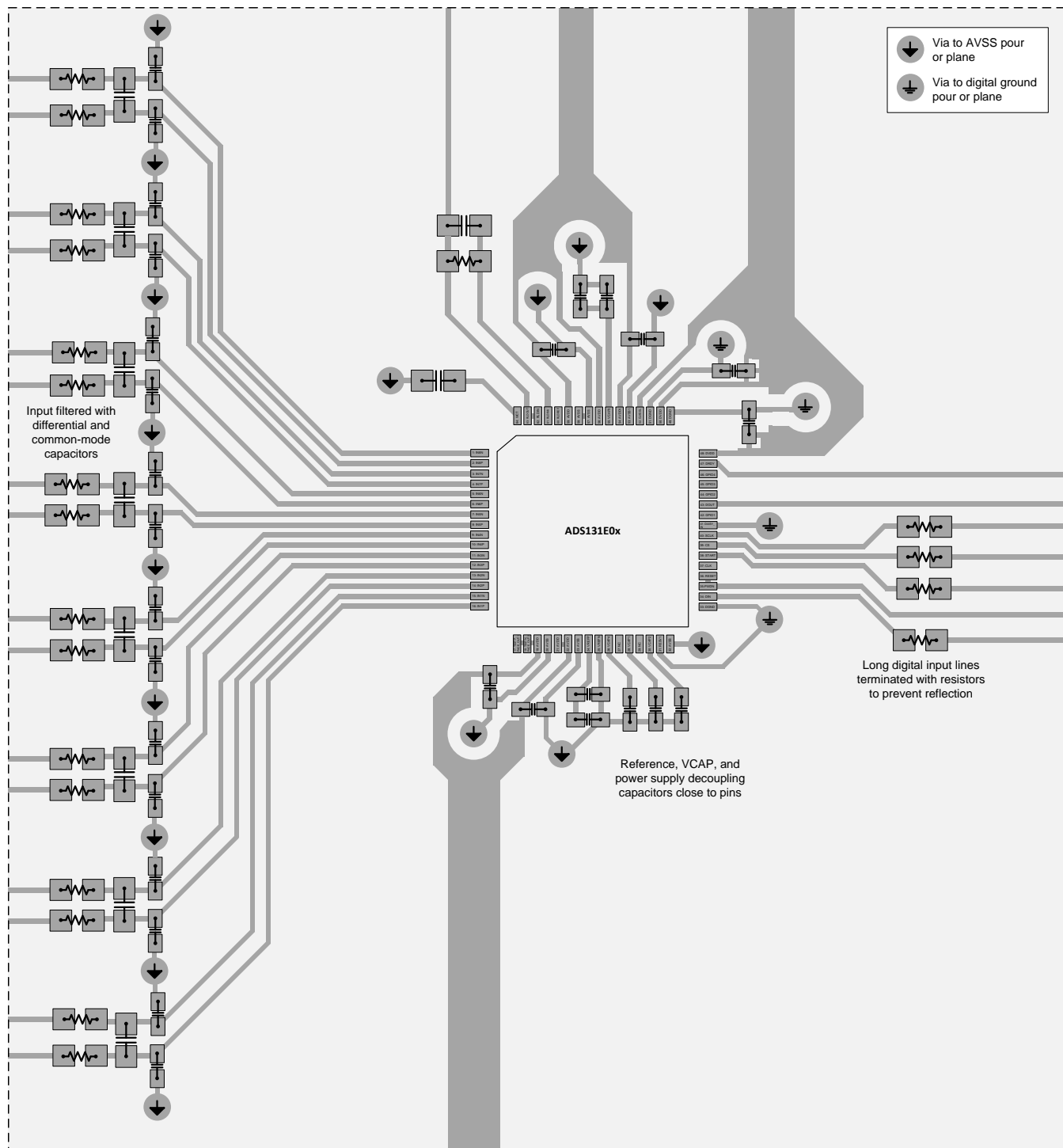


Figure 69. ADS131E0x Layout Example

## 13 Device and Documentation Support

### 13.1 Device Support

#### 13.1.1 Third-Party Products Disclaimer

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### 13.2 Related Links

[Table 24](#) lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 24. Related Links**

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ADS131E04	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
ADS131E06	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
ADS131E08	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 13.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 13.4 Community Resource

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 13.5 Trademarks

E2E is a trademark of Texas Instruments.

SPI is a trademark of Motorola.

All other trademarks are the property of their respective owners.

### 13.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 13.7 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ADS131E04IPAG	ACTIVE	TQFP	PAG	64	160	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E04	<a href="#">Samples</a>
ADS131E04IPAGR	ACTIVE	TQFP	PAG	64	1500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E04	<a href="#">Samples</a>
ADS131E06IPAG	ACTIVE	TQFP	PAG	64	160	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E06	<a href="#">Samples</a>
ADS131E06IPAGR	ACTIVE	TQFP	PAG	64	1500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E06	<a href="#">Samples</a>
ADS131E08IPAG	ACTIVE	TQFP	PAG	64	160	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E08	<a href="#">Samples</a>
ADS131E08IPAGR	ACTIVE	TQFP	PAG	64	1500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	ADS131E08	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TRAY**


Chamfer on Tray corner indicates Pin 1 orientation of packed units.

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
ADS131E04IPAG	PAG	TQFP	64	160	8 x 20	150	315	135.9	7620	15.2	13.1	13
ADS131E06IPAG	PAG	TQFP	64	160	8 x 20	150	315	135.9	7620	15.2	13.1	13
ADS131E08IPAG	PAG	TQFP	64	160	8 x 20	150	315	135.9	7620	15.2	13.1	13

PAG (S-PQFP-G64)

PLASTIC QUAD FLATPACK



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Falls within JEDEC MS-026



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
  - D. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PAG (S-PQFP-G64)

PLASTIC QUAD FLATPACK



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  - B. This drawing is subject to change without notice.
  - C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
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